ERICSSON

MAINTENANCE MANUAL **SYSTEM MODULE 19D902590G1-G3**

TABLE OF CONTENTS	
	Page
DESCRIPTION	Front Cover
CIRCUIT ANALYSIS	Front Cover Front Cover 4
ASSEMBLY DIAGRAM	6
PARTS LIST	7
System Board	9 10
SCHEMATIC DIAGRAM System Board	11 17
IC DATA	20

DESCRIPTION

System Module 19D902590 contains all audio processing and control circuitry for the T/R Shelf. The audio processing and routing is done using analog circuitry. The control circuitry utilizes high speed digital components, and includes a microprocessor.

System Module 19D902590G3 is a 19D902590G1 System Module with a "piggyback" Digital Signal Processor (DSP) board (19D902667G1). Due to the high speed digital circuitry, the System Module is housed in an RFI and EMI shield.

Supply voltages for the System Module and DSP board are generated by the Power Module and applied to the System Module through the backplane. All audio and control signals are routed to the System Module through the 96-pin DIN connectors on the backplane board.

CIRCUIT ANALYSIS

SYSTEM BOARD

Clock Circuitry

The 14.7456MHz clock drive for the System Module's digital circuitry is derived from a gate oscillator circuit comprised of U21C, U21D, Y1 and associated components. R110 keeps the inverter gate U21C in the linear mode during power-up for reliable clock start-up. R111 and C3 provide AC $\,$ and DC drive to crystal Y1. U21D buffers the clock signal, and Q11 and Q12 are provided to allow the microprocessor (U1) to adjust the clock frequency.

When the microprocessor pulls P4.5 (pin 60) low, Q11 and Q12 are turned on. Capacitors C52 and C53 are then switched into the circuit, changing the capacitive loading on the crystal Y1. This causes the oscillation frequency to change approximately 300 ppm.

Reset and Watchdog Timer

The System Module contains a power-on/manual reset circuit to initialize the programmed code and hardware devices on the board. The reset circuitry, U19, monitors the +5V line, and outputs a low-going pulse on U19 pin 15 as well as a high-going pulse on U19 pin 16 when the voltage on the +5V line is below +4.5V. Manual reset is also possible by pulling the reset line on J1-18C low. This is accomplished through reset switch S1 on the Power module. U19 also provides added protection to EEPROM U6 to ensure data integrity. If the +5V line falls below 4.65V, U19 inhibits any chip selects to U6 which might occur during power transients.

In addition, U19 provides a watchdog timer. The microprocessor must pulse pin 11 of U19 periodically or U19 will generate a reset. The microprocessor pulses the watchdog timer using pin U1-40.

The reset pulse is applied to microprocessor U1, to the PPI U34, and to the Backplane Board on J1-18C.



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Address Latch

The main controller on the System Module is the 80C152JB microcomputer (U1). The microcomputer obtains its instructions from the program stored in PROM U4. This can be either a 32k-byte or 64k-byte device.

The lower eight bits of the address from the micro-computer multiplex between address and data. A 74HC373 address latch (U2) is used to latch the address from the microcomputer using the microcomputer's ALE signal (U1-55). The upper eight bits of the address contain only address information, and is applied directly to all devices needing these additional address lines.

Address Decoding

A 74HC138, one-of-eight de-multiplexer (U3) is used for address decoding. The three most significant bits of the address bus (A13, A14, and A15) are used to select one of eight, 8k-byte blocks of data (non-program) memory.

The microprocessor's PSEN output signal at U1-54 is used to disable demultiplexer U3, causing all of its eight select outputs to go high so only the program PROM U4 will be selected during accesses of program memory. This prevents bus contention on the AD lines. The following devices are mapped to an 8k-byte block of data memory:

U3-15	0000-1FFFH	EEPROM (U6)
U3-14	2000-3FFFH	RAM (U5)
U3-13	4000-5FFFH	Digital Signal Processor
U3-12	6000-7FFFH	Input/Output Latches
		(U7, U25)
U3-11	8000-9FFFH	82C54 Counter Timer
		(U29)
U3-10	A000-BFFFH	82C55 Programmable
		Peripheral Interface (U34)
U3-09	C000-DFFFH	not used
U3-07	E000-FFFFH	not used

Program/Data Memory

Three memory components are included in the System Module: a UVEPROM (U4), a static RAM (U5), and an EEPROM (U6). The microprocessor can address two 64-kbyte memory segments; the program memory and data memory. The program memory is stored in UVEPROM U4 and is selected by a low going pulse on the microprocessor's PSEN output (U1-54).

The low going pulse on the PSEN output disables access to any data memory by disabling address decoder U3. This disables all chip selects to devices mapped to data memory locations. (Refer to the Address Decoding section for more information on devices mapped into the data memory space.)

The microprocessor executes program instructions fetched from the UVEPROM U4. The microprocessor outputs the pro-

gram address on AD[0:7] and A[8:15]. The address latch latches the address on AD[0:7] when ALE goes high. The UVEPROM inputs the 16-bit address and outputs the eight-bit instruction found at the input address on the AD[0:7] lines when PSEN goes low.

Data memory is stored in static RAM U5. Data can be written to, and read from this device. However, all data is lost at power off. The RAM inputs the latched address output by the microprocessor when its chip enable input (U5-20) from address decoder U3 is low. If the RAM's OE input (U5-22) goes low, then data contained in the RAM at the input address is output to the microprocessor on the AD[0:7] lines. If the RAM's WE input (U5-27) goes low, then data on AD[0:7] is stored in the RAM at the input address.

Personality information is stored in EEPROM U6. Data can be written to and read from this device. Data stored in this device is not lost at power off. The EEPROM inputs the latched address from the micro-processor when its CE input is low. The chip enable input is generated by address decoder U3 and output on U3-15. However, the signal is routed through U19.

U19 disables an EEPROM chip enable when the board is in a reset condition. This is to ensure that no extraneous writes occur to the EEPROM during powerup or brown out conditions which would affect personality data.

If the EEPROM's OE input (U5-22) goes low while the CE is low, then data contained in the EEPROM at the input address is output to the microprocessor on the AD[0:7] lines. If the EEPROM's WE input (U5-27) goes low while the CE is low, then data on AD[0:7] is stored in the EEPROM at the input address.

Counter-Timer IC

Counter timer U29 consists of three 16-bit timer/ counters which are used for different functions de-scribed below. The microprocessor can enable, disable, and configure the counters, as well as read back counter status information from the device using its AD bus. The input clock to the device is derived by dividing by two the 14.7456 MHz clock signal out of the gate oscillator buffer U21D using D flip-flop U28. This same 7.3725 MHz clock signal is used for each counter/timer to give 135nanosecond resolution.

Counter 0 is used for channel guard decoding. It is configured to output a 135-nanosecond pulse on U29-12 at eight times the channel guard decode frequency. This pulse is latched by D flip-flop U18A. The output of this latch is applied to the INTO input of the micro-processor (U1-16), causing an interrupt. The micro-processor resets the latch, clearing the interrupt by pulsing U18A pin 4 using its P1.6 (U1-10) output in the interrupt service routine.

The 135-nanosecond pulse on U29-12 also causes a sample of the limited channel guard signal LIM_CG to be taken. This sample is brought into the microprocessor during the INTO service routine on P4.7 (U1-58) and used for channel guard decoding.

The second counter/timer (counter 1) is used to generate a microprocessor interrupt. This interrupt is used by the microprocessor to generate channel guard and should occur at eight times the channel guard encode frequency. The counter is configured to send its output (U29-16) high upon timing out. This high is inverted by NPN transistor O9, R1, and R18.

The inverted signal is then applied to the micro-processor's INT1 input (U1-18) which causes an interrupt to occur. The counter is reloaded by the interrupt service routine software. This causes U29-16 to return low, which clears the interrupt.

The third counter/timer (counter 2) is used for tone generation. When a tone is desired the microprocessor configures the counter/timer to output a square wave on U29-20 at the desired frequency. This square wave is then bandpass filtered by active filter stages U17C and U17D to remove undesired harmonics, and to create a sine wave.

A resistor divider consisting of R38 and R39 sets the level of the sine wave at U17D-14 to approximately 800 millivolts rms. The microprocessor disables the counter/timer when no tone is desired.

Programmable Peripheral Interface

Programmable Peripheral Interface (PPI) U34 provides three additional eight-bit I/O ports. The reset generated by supervisory IC U19 is input on U34-39 and serves to reset the IC to its default state. Ports A and C are configured as output ports, and Port B as an input port.

Port C outputs are used to load the Rx and Tx Synthesizers as well as to provide serial communications with the Interface Board. Port A outputs provide an interface to the GETC in stations so equipped. The System Module loads the synthesizers and communicates with the Interface Board with the following Port C signals: RXF4/AUX2 (DATA), RXF2 (EN-ABLE), TXF1 (A0), TXF2 (A1), RXF1 (A2) and from Port A: SERIAL CLK (CLK). The remaining Port A and Port C outputs are used for several different interfaces.

Port B inputs several interface signals. Pullup resistors to +5V are used on all open collector type inputs. These signals are then buffered and/or level shifted where appropriate. Resistors are put in series with all of the inputs for spike protection.

Where a level shifter/buffer (U41) is not used, dual diodes are included to prevent over/under voltage conditions.

The RUS input uses an NPN transistor (Q4) to convert the signal to CMOS logic levels.

Microprocessor I/O The microprocessor has some additional I/O pins. These pins are used to bring signals in and out of the microprocessor directly without going through any additional I/O devices such as latches or a PPI. The LOCAL PTT input is level shifted and buffered by U41E and brought into the microprocessor on U1-19.

The microprocessor also generates the AUX RX MUTE output used to mute an auxiliary receiver. The signal originates on U1-51 and is inverted by U26F. This gives an open collector active low output.

The EXT LSD SEL, LINE IN SEL, LSACO, and 4W **DUPLEX** signals are also generated by the microprocessor. These signals go to the analog circuitry and control audio routing through analog switches.

LBI-38764

Additional I/O Latches

Additional I/O is provided by input latch U25 and output latch U7. Each of these latches are mapped to address 6000h. However, input latch U25 is enabled by a low pulse on the microprocessor's RD output while the output latch U7 is enabled by a low pulse on the microprocessor's WR output.

The input latch is used to get DC CNTRL, BATT STDBY, REM PTT, TX DISABLE, GG MON, and M3_STATUS signals onto the AD bus so they can be read by the micro-processor. The DC control currents are decoded elsewhere in the system, and the decode current is passed to the microprocessor using the DC CNTRL 1, DC CNTRL 2, and DC CNTRL 3 inputs. These are CMOS level signals, so no level shifting is required.

The BATT STDBY signal requires level shifting to convert the 22-volt high to a TTL level. This is achieved by R4 and R5. Dual diode D2 limits the signal to be within -0.7V to +5.7V to guard against over/under voltage conditions. BATT STDBY is driven high when the station is operating from AC line power and floats low due to a weak pull down resistor when the station is operating from battery power.

The 74HC377 output latch latches the data on the AD bus when the chip is selected by address decoder U3 and a low going WR pulse is received. This latched data goes to analog switch select lines used to select audio paths in the analog circuitry.

The microprocessor is also capable of loading electronic potentiometers U35 and U36. Each of these potentiometers contains two, 256-position variable resistors. The microprocessor must serially load all four variable resistors at the same time.

The microprocessor switches the potentiometer's select line (U1-17) high. This enables the electronic potentiometer's loading circuitry and allows the micro-processor to shift 34 bits of serial data into the electronic potentiometers, 17 bits of data into each IC.

Data is output on U1-20 and clocked into U35 and U36 on the rising edge of the clock signal generated by the microprocessor on U1-21. The microprocessor can also read back the current potentiometer settings.

When data is clocked into U35 and U36, the current potentiometer setting is clocked out and brought into the processor on U1-22. After all 34 bits have been clocked into U35 and U36, the microprocessor pulls the potentiometer's select line (U1-17) low. This ends the loading sequence, and causes the digital potentiometer's to load the new resistance value.

A/D Converter

The System Module contains an A/D converter. This is used for metering DC inputs. Four external metering inputs are accommodated. These include PWR SNSR, TX MTR+ relative to TX MTR-, RX MTR+ relative to RX MTR-, and EXT JCK.

The PWR SNSR input will accommodate a DC level between zero and +5V relative to analog ground. The input is protected from over voltage conditions by dual diode D7.

The Control Shelf routes TX MTR+ and TX MTR- into a differential amplifier consisting of U17A, R140, R142, R145, and R146. This amplifier removes any common-mode voltage. The output of this differential amplifier is actually measured and must be between zero and +2.9 Volts.

The RX MTR+ input is assumed to be between zero and +5V relative to analog ground. No conditioning is performed except for dual diode D3 that protects from over/under voltage conditions.

The EXT JCK input is designed to input signals between zero and +10V relative to AGND. Operational amp U17B provides a high input impedance and buffers the input signal. The output of this amp goes through a voltage divider network composed of R3 and R6 that divides the DC level by two. This signal is then routed to the multiplexer U33.

Analog multiplexer U33 gates one of four inputs to the A/D converter U27. The microprocessor determines which input is selected using U1-52 and U1-57. The microprocessor starts an A/D conversion by putting a rising edge on U27-5. U27 then converts the DC input voltage selected on U33 to a digital value.

The converted digital value is clocked out of U27 sequentially by the microprocessor, beginning with the most significant bit. The microprocessor selects U27 by setting U27-5 low. When the A/D converter is selected it puts the MSB of the eight bit conversion data on U27-6. This is read by the microprocessor. Successive data bits are clocked out of the A/D converter on falling edges of its CLK input (U27-7).

When all eight bits have been clocked out, the A/D converter is deselected, and the next conversion cycle begins by the microprocessor setting U27-5 high.

DSP Interface

System Module 19D902590G3 is equipped with plugs to accommodate Digital Signal Processor (DSP) "piggyback" board 19D902667G1. The board plugs into J2 and J3 of the System Module.

The microprocessor communicates with the DSP board through its eight-bit AD[0:7] bus, using a dual port RAM located on the DSP board. This memory is mapped into an 8k-byte data memory segment using address decoder U3. Data can be written to and read from any of the 256 byte locations that can be addressed by AD[0:7].

The DSP board contains an address latch to latch the address information on AD[0:7] when ALE goes high. When the DSP CS is low and the microprocessor WR output is low, the data on AD[0:7] is written into the latched DSP data memory segment address. When DSP CS is low and the microprocessor RD output is low, data on AD[0:7] is read into the microprocessor U1 from the latched DSP data memory segment address.

Two handshake lines used for the DSP interface for synchronization are **DSP TBLF** and **DSP RBLE**. When the DSP has written a message to the dual port RAM, it signals microprocessor U1 by asserting DSP TBLF low. The microprocessor then reads the message from the dual port RAM and then resets DSP TBLF high to tell the DSP that it is ready for another message.

When the microprocessor wants to send a message to the DSP it first looks at the DSP RBLE input. A high on this input indicates that the DSP receive buffer is empty and it is ready to accept a new message. When the microprocessor has written the message to the dual port RAM, it asserts DSP RBLE low to signal the DSP that it should read the new message. The DSP resets DSP RBLE high after it has read the message.

The microprocessor can reset the DSP board by setting U1-7 high. The high is inverted by O10, and the resulting low resets the DSP board.

RS232 Interface

The System Module has an RS232 serial port for programming and diagnostics. RS232 data is received on the PGM RXD input and converted to TTL levels by U22A. The TTL

data is brought into the micro-processor's internal UART on pin U1-14. Transmit data is output on U1-15 by the microprocessor, and level shifted to RS232 levels by U22B. The RS232 data is output on **PGM TXD**.

GSC Interface

A high speed serial interface that is referred to as a global serial channel (GSC) is also included on the System Module. Data is transferred bidirectionally over an RS485 differential pair made up of COMM+ and COMM.

When the microprocessor wants to send data over the GSC, it enables the drivers in U24 by outputting a low on U1-6. Data is generated internally in the micro-processor and output on U1-5. The data is converted to RS485 levels and output on the GSC by U24.

The receiver section of U24 is always enabled so that the microprocessor's receiver can monitor the transmitted data. This monitoring is to check for collisions on the GSC created by multiple GSC nodes transmitting simultaneously.

U24 converts received data to TTL levels and outputs them on U24-1. The microprocessor brings the TTL level data into its receiver on U1-4 for message decoding.

Transmitter Interface

The System Module is responsible for loading the Tx Synthesizer Module with its' proper frequency information. When the micro-controller sees a PTT from an enabled source, it first drives ANT RLY active. This switches the antenna switch in stations with this option and also applies power to the Tx synthesizer oscillator circuit. Next, data is shifted into the Tx Synthesizer using A2, A1, A0, CLK, and DATA. After the TX Synthesizer has been loaded with data, ENABLE goes active for 10 mS to allow the TX Synthesizer PLL circuit time to acquire frequency lock. At the end of this ENABLE period, the micro-controller samples the TX Synthesizer status bit supplied by the Interface Board. If there is no fault (synthesizer locked) then the micro drives TX OSC CNTRL (PA KEY) active which turns on the RF PA. Upon reset or a channel change, the System Module must also set the PA power pot by sending appropriate data to the Interface Module.

Audio for transmission is output on the TX AUDIO HI and TX AUDIO LO outputs. Channel guard is summed into TX AUDIO HI.

Receiver Interface

At power up or upon channel change, the RX Synthesizer is programmed in the same manner as the TX Synthesizer. Carrier activity on the selected channel is sensed by the receiver's squelch circuitry and applied to the System Module on the CAS input. This active high input is level converted by Q8, and

applied to the microprocessor on U1-23. The microprocessor then routes audio according to the station's configuration programming.

Local Controls

The System Module has three switches and LEDs for local control. Switch S2 is a REMOTE PTT switch. When not activated, R23 pulls the line to +5V. When activated, S2 pulls the line to ground. This switch is input on pin 7 of input latch U25. The line is also routed to the external connector to allow an external module to activate the remote PTT input. A low on this input causes the microprocessor to react as though a PTT has been received over the line.

Switch S3 is a TX DISABLE switch. When not activated, R136 pulls the line to +5V. When activated, the switch pulls the line to ground. This switch is input on pin 8 of input latch U25. When S3 is activated, the microprocessor inhibits all transmissions.

Switch S4 is a CG MONITOR switch. When not activated, R137 pulls the line to +5V. When activated, the switch pulls the line to ground. This switch is input on pin 9 of input latch U25. The line is also routed to the external connector. This allows an external module to activate the CG MONITOR input, or to examine the state of the CG MONITOR input. A low on this input causes the microprocessor to switch into channel guard monitor.

The System Module concurrently activates the ANT Relay output and LED DS1. When the System Module is in CG MONITOR, it lights LED DS3 by outputting a high on U1-66. This high is inverted by U2D. This allows current to flow through DS3, turning on the LED.

Putting the System Module in the transmit disable mode lights LED DS2 by outputting a high on U1-67. This high is inverted by U26C. This allows current to flow through DS2 to turn on the LED.

CG Filter, High Pass and De-emphasis Amps

Receiver audio is applied to the System Module "VOL/SQ HI" port on J1-2B. U37A buffers the input signal and removes any Dc bias. With an input of 1 Vrms at 1000 Hz, the output is typically 2 Vrms and is supplied to three places; channel guard reject filter, the DSP board through DSP unfiltered audio, and channel guard decode.

U30A is a unity gain notch-filter, centered at 205 Hz. The filter provides 25 dB of attenuation. U30B, U30C, and U30D form a sixth order, unity gain high-pass filter, with a cut-off frequency of 280 Hz. U37B is a + 1/-3 dB de-emphasis filter that rolls the audio off at 6 dB-per-octave in the frequency range from 300-3000 Hz.

With 1 Vrms into VOL/SQ HI, the output of U37B will be 750 millivolts rms. This output is supplied to four places; U8A, TX Audio out, Line Audio out, and the summing amplifier with the optional auxiliary receiver input. U8A is controlled by the microprocessor to switch between MIC and VOL/SQ audio to the DSP. The combination of U37A, U30A, U30B, U30C, U30D, and U37B provide the frequency envelope-shaping requirements (roll-off) as shown in Figure 1.

The TX Audio Out circuit consists of U15, U36A, U8C, and U37D. U15 is an analog multiplexer which is controlled by the microprocessor. Any of the following signals can be connected to the TX AUDIO HI output; LOCAL MIC, VOL/SQ, DSP LINE/TX AUDIO, DSP TX AUDIO, External High Speed Data, LINE Input, open (battery alarm), and Ground (for no transmission). U8C is an analog mux which is controlled by the microprocessor to sum CG into the TX AUDIO output and increase the TX AUDIO gain on U37D.

Battery Alarm/Morse Code is summed with the output of U15. This allows for transmission of the alarm signal when other signals are present. U36 is a dual-digital potentiometer which is controlled by the microprocessor, and adjusts the transmit audio level. U37D is a gain stage which drives the TX AUDIO HI output. The level at TX AUDIO HI (J1-5C) and TX AUDIO LO (J1-6C) is adjustable between 40 and 250 millivolts rms.

U37C is the +2/-8 dB de-emphasis filter which provides a 6 dB per octave roll off from 300-3000 Hz for the local intercom or speaker audio. With a rated input of 1 Vrms at 1000 Hz, the output level of this filter is 750 millivolts rms. This filter, in combination with U37A, U30A, U30B, U30C, and U30D provide the frequency response shown in Figure 2.

U32 is the analog multiplexer for the INTERCOM Audio output. It allows for selection of VOL/SQ audio, LINE Input audio, Voice Guard summing, and DSP LINE/TX AUDIO. Amplifier U31C sums the multiplexed audio with Voice Guard tone. The resulting signal is applied to J1-7A.

CG/LSD Decode Filter

Received audio is coupled through a low pass filter to remove the audio, leaving only Channel Guard (CG) or Low Speed Data (LSD) information. A hard limiter then converts the signal into a digital square wave. The square wave is decoded in software as well as the 135-degree phase shift for STE.

U9A is a gain stage which supplies two frequency-dependent, negative resistor (FDNR) circuits. The first FDNR consists of U10A and U10B, and has a cut-off at 205 Hz. The second FDNR, formed by U10C and U10D, has a cut-off at 230 Hz.

U11B is a low pass filter which provides added attenuation in the 300-3000 Hz range. These elements combine to provide

35 dB of attenuation for frequencies above 310 Hz. The resulting frequency response is shown in Figure 3.

U11A, D5, and Q2 combine to convert the analog signal at the U11B output to a 0-5 Vdc square wave. This square wave is then supplied to U18B to be read and decoded by the microprocessor.

CG/LSD Encode Filter

U12C is used to select between external low speed data or WALSH bits. The WALSH bits are created by the microprocessor on pins U1-64 and U1-65, and form a rough sine wave. This signal is coupled through U9C to provide some gain.

U16A, U16B, U16C, and U16D form two FDNR circuits which have the same response as described in the CG/LSD DECODE FILTER section. U9D provides gain and drives U35A. U35A is a digital potentiometer which provides level adjustment and is controlled by the microprocessor. Also, U9B has a 3.3 k-ohm source impedance to allow a separate source to drive Channel Guard HI. This filter has the same response as shown in Figure 3.

Local Mic Input

The local microphone input at J1-3A and J1-3B supplies 12-Volts dc level to power the microphone. This input is buffered through U13A, which removes the DC bias and amplifies a 100-millivolts rms input for a 775-millivolts rms output.

Battery Alarm/Morse Code

The Battery Alarm/Morse Code tones are generated using U29, U17C, and U17D. U29 is a Clock Timer which creates a square wave at the required frequency. C113 and R39 form a high pass filter to provide DC blocking. U17C is second order low pass filter and U17D provides gain. These components combine to provide the response shown in Figure 4.

The output of U17D sources the signal to U31B and U15. U15 is the TX AUDIO multiplexer discussed earlier in this section. U31B is an amplifier to sum the Battery Alarm signal with the Voice Guard Alert tone, which is then transmitted to the LINE Output.

Line Audio And Compression

The LINE output circuit consists of U14, U8B, U36B, U31D, U13B, and U31A. The analog multiplexer U14 is used to connect one of the following signals to the LINE driver U31D; LOCAL MIC, VOL/SQ, auxiliary receiver, aux receiver/VOL/SQ, DSP LINE/TX audio, MODEM LINE Data, open and Ground. The open state is to transmit Battery Alarm or Voice Guard Alarm.

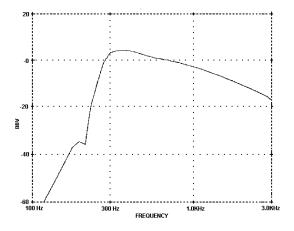


Figure 1 - Channel Guard Tone Reject (+1, -3 dBV)

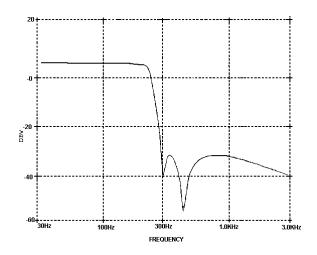


Figure 3 - Channel Guard Encode/Decode Filter

LBI-38764

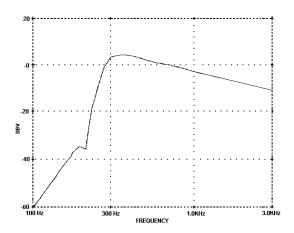


Figure 2 - Channel Guard Tone Rejct Filter (+2, -8 dBV)

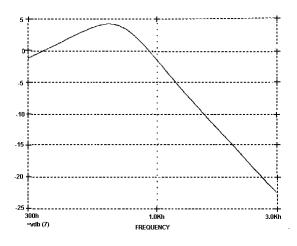


Figure 4 - Battery Alarm/Morse Code Band-Pass Filter

U31A sums the aux receiver audio with the VOL/SQ audio. U36B is a digital potentiometer and controls the audio level into the line driver U31D. The level at LINE A (J1-4B) and LINE B (J1-4A) is adjustable between -20 dBm and +11 dBm.

The LINE IN audio is selected from LINE A and LINE B in a two-wire system, and from DUPLEX LINE A and DU-PLEX LINE B in a four-wire system. Each input has a 600ohm impedance to match the line impedance. U12B selects between two-and four-wire audio.

Digital potentiometer U35B sets the level applied to the line compensation filter U13B. This filter can be set up to compensate for high frequency roll-off on long lines by removing R16. This modification should be used when roll-off in the 2500 to 3000 Hz range is more than 10 dB below the 400 to 600 Hz level.

Following U13B is the compression circuit consisting of U13C, U13D, D6, and Q3. LINE IN audio from U13B is applied to a network composed of R65, Q3, R75, and R76. After being amplified by U13C, the output is supplied to four places: Line Output, TX Audio output, Intercom audio, and D6.

This compensation circuit is only effective in stations using Group 1 System Modules (no DSP) or Group 2 modules programmed for DC Remote Control. For all other applications, audio routing bypasses the compensation filter.

The output of amplifier U13C is rectified by D6 which charges C25. U13D amplifies the voltage on C25 and provides a DC offset to the gate of Q3. Q3 serves as a variable resistor in the voltage divider composed of R65 and Q3 which limits the input to U13C. R75 and R76 serve to reduce distortion across the voltage divider.

This circuit normally operates in a linear fashion with Q3 turned off which appears as a high resistance. When higher than normal audio is received at U13B, the amplification of U13C is rectified by D6, increasing the voltage across C25.

The increased voltage across C25 through U13D starts turning on Q3 reducing its drain to source resistance, which in turn, lowers the audio to U13C. Since this affects not only the output of U13C, but the turn-on voltage of Q3 from U13D, a steady audio output is provided.

-NOTE

<u>Service Note</u>: The compressor can be disabled by removing Q3. The compressor is typically disabled when shipped from the factory. It is preferable to use the compressor function on the DSP board. If this hardware compressor is used, install Q3 (19A703795P1; sim to 4416) on System Board (19D903771G1).

DSP BOARD

The **D**igital **S**ignal **P**rocessing (DSP) Board utilizes both digital and analog integrated circuits (IC's) to offer a compact, flexible, and reliable solution for audio signal analysis and modification. Most of the components are surface mounted.

The DSP Board operates with two channels of audio. It conditions the audio inputs, digitizes the audio, and processes the audio data in software. The DSP Board then sends the transformed audio to analog outputs, and the signal analysis information to its digital output.

Audio inputs from the System Module board are DSP_FILT_VOL/SQ, DSP_UNFILT_VOL/SQ, and DSP_LINE_IN. These signals are selected and conditioned through U10, U11, and U15. The signals are then sampled and digitized by U4 and U5. The digital audio data is then applied to U1 for processing. After processing, the audio data is returned to U4 and U5 for digital to analog conversion. The transformed audio is applied to the System Module board on DSP_TX_AUD and DSP_LINE/TX_AUD.

All pertinent information from the DSP analysis of the audio is communicated digitally to the System Module through the dual port RAM, U12. Messages are written to this piece of memory by the DSP micro-computer, U1. The messages are read from the memory by the System Module (via the digital signals of connector P3).

For clarity, the DSP circuitry is analyzed in the following order:

- 1) DSP and supporting circuitry
- 2) Analog Input/Output
- 3) Parallel communication port

DSP Microprocessor

The DSP Board performs its functions in the ADSP-2101 Digital Signal Processing Microcomputer, U1. This chip requires external hardware to function.

Crystal (Y1) provides the 8.192 MHz clock required by the DSP microprocessor. Capacitors C16 and C17 provide the loading required for reliable start-up and stable oscillation.

The DSP microprocessor can read or write to both internal and external data memory. Two identical 8K X 8 static RAM's (U2 & U3), are used to form an 8K X 16 external data memory space. External 16-bit data memory is applied to the DSP on D8-D23. U3 holds the most significant byte (MSB), and U2 holds the least significant byte (LSB). For a single external memory address, U3 stores D23 through D16, and U2 stores D15 through D8. A 16-bit word is formed in order to maintain compatibility with the processor's internal 1K X 16 data memory architecture.

When the processor attempts to address data memory which exceeds that which is available internally (1K X 16), the address bus, A12 through A0, sets up an external address. The data memory is enabled by a low on **/DMS**. A read or write is activated by a low on the **/RD** or **/WR** pin. The external data memory access is completed when address pins return to their high impedance state, **/RD** or **/WR** returns to high, and **/DMS** rises to logic high.

DSP microprocessor U1 operates from a 2K internal program memory. This program RAM is volatile; it is lost during poweroff sequences. Therefore, it is necessary to have non-volatile memory to safely hold the DSP Board code. The 16K X 8 EPROM (U6) performs this function.

Upon reset, or during a "re-boot", up to 2K x 24 of internal program memory is loaded from this external "BOOT EPROM." The Boot EPROM, U6, holds up to eight different pages which can be loaded. The selection of a 2K-page of code is software-controlled except during reset when boot page zero is always loaded.

In essence, boot memory page loading is a sequence of "read" cycles. The BMS pin goes low in order to enable the boot memory chip. Addresses are sequenced on lines A0 through A13, D22 and D23. The/**RD** pin activates the data bus, D15 through D8, for each transfer of program memory into the internal program memory space.

The boot EPROM circuitry also includes resistors R1 and R2. These resistors are zero ohms, and are equivalent to jumper wires. If the capability of 8 boot pages is necessary, R2 is removed, and R1 is installed on the board. In this case, U6-pin 1 acts as an extra address pin which is connected to D23. If the capability of 4 boot pages is necessary, R1 is removed, and R2 is installed on the board. In this case, U6 pin 1 acts as a program pin, and is tied off to five volts.

Analog Inputs

The DSP Board inputs and processes audio from both the receiver and the line simultaneously. There are two possible receiver audio input settings and two possible line audio input settings. These are:

(1) **DSP_FILT_VOL/SQ** or **DSP_UNFILT_VOL/ SQ** input, and

(2) Two-wire line input or four-wire line input.

This audio selection is actuated directly by the DSP but is user-programmable. The DSP uses the address multiplexer, U8, to select U7, a D-flip flop register. This is accomplished by setting A13-A11 to binary 100 when **/PMS** goes low. Such a sequence will cause U8-pin 14 to go low, enabling data to pass through the D-flip flops upon **/WR** going low and then high. D8 and D9 are written to the outputs of U7 (pins 2 and 5) as **VOL/SQ_SEL** and **CANCEL_SEL**.

Depending upon these signals, digitally-controlled analog switches (U10) route the appropriate signals to achieve the final audio input settings described above. If VOL/SQ_SEL is a logic high, DSP_UNFILT_VOL/ SQ is selected; otherwise DSP_FILT_VOL/SQ is selected. If CANCEL_SEL is a logic high, four-wire operation is selected. If not a logic high, two-wire operation is selected.

Each audio channel selection requires proper voltage level adjustment to insure an optimal conversion to the digital domain where it will be processed. This conversion is performed by codecs U4 and U5. In other words, the analog audio signals are conditioned to assure that their dynamic ranges can be accommodated by the codecs. The codecs will neither be under-driven nor saturated. This results in a digital audio signal with uniform Signal-to-Noise Ratio (SNR) following the codec A/D conversion.

Filtered Receiver Input Conditioning

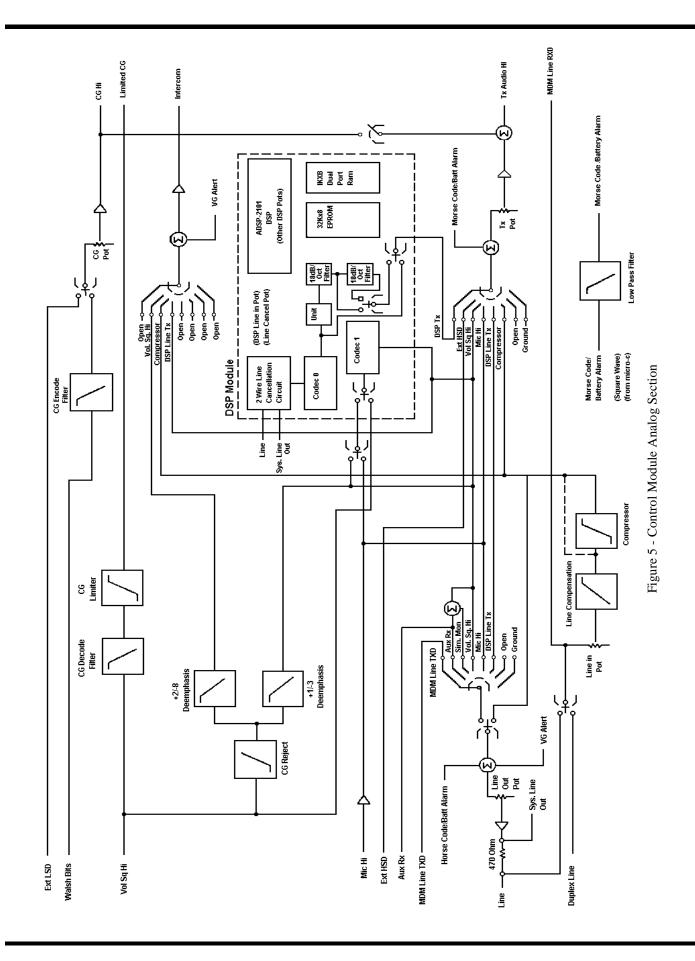
Filtered receiver input comes from the System Module following de-emphasis and channel guard reject filtering at a maximum of 1.16 Volts rms. This input channel requires no amplification to assure that codec U4 utilizes its dynamic range efficiently.

The amplification factor is determined by resistors R5 and R6. The gain is one. Therefore, the maximum input voltage to the codec is 1.16 Volts rms.

Four-Wire Line Input Conditioning

Four-wire line input comes from the **DPLX** line input pair of the Control Shelf when it is in a four-wire configuration. Its audio is not in contention with audio which is leaving the station because there are two lines independently dedicated for the output signal.

The line audio level-adjustment is able to attenuate a 2.47 Volts rms (+11 dBm) signal, and amplify a 77.3 mVrms (-20 dBm) signal to the maximum input level of a codec (approximately 1.4 Volts rms). This is to compensate for up to 30 dB of line loss that can occur between the Remote Control Unit and the station.



In the four-wire configuration, DSP_LINE_IN is pro-pagated to TP1 with only a gain of 1.09 provided by the differential instrumentation amplifier circuit of U11(A,B,C) and R12-R17. This occurs because the amount subtracted from **DSP LINE IN** is **AGND** (U10A pin 13).

Between TP1 and TP2 there is a digitally controlled variable gain stage. The gain stage is composed of U11D, U15(1), R18, and R20. The DSP addresses (and serially loads) a resistance from 0 to 10K-ohms into the dual programmable potentiometer, U15. The digitally-controlled impedance, along with R18 and R20, form a gain through operational amplifier U11D.

The DSP uses address multiplexer U8 to select U7, a D-flip flop register. This is accomplished by setting A13-A11 to binary 100 when /PMS goes low. Such a sequence will cause U8-pin 14 to go low, enabling data to pass through the D-flip flops upon /WR going low and then high.

Data is written to the D10, D11, and D15 outputs of U7 (pins 6, 9, and 19) known as **POT CLK. POT LOAD EN**. and POT_IN which directly control U15. POT_CLK is a serial clock. POT IN is serial data. POT LOAD EN is a serial load enable. During a "load" cycle, POT_LOAD_EN is held high. Seventeen POT_IN values are set up and held with respect to the rising edges of **POT** CLK. The first value loaded into the dual programmable potentiometer is a "don't care" value. The following sixteen values comprise two 8-bit wiper positions. Wiper 1 gets loaded before wiper 0. Loading is specified from MSB to LSB.

Two-Wire Line Input Conditioning

Two-wire line input comes from the Line input of the System Module when it is in a two-wire configuration. This audio is in contention with audio which is leaving the station on the same two-wire pair. The DSP Board must cancel out the interfering output audio from the input. In addition, it must amplify the input signal to account for the line loss of up to 30 dB that can occur between the Remote Control Unit and the station.

Cancellation of transmit audio from receive audio on the two wire pair is accomplished by the differential instrumentation amplifier consisting of U11(A,B,C), R11-R17, and the DSP-controlled resistance through U15(0) and R10. The SYSBD LINE OUT (a DSP Board input signal) is limited by U18A and level adjusted through the programmable potentiometer, U15(0), (as explained above) and then subtracted from the line input signal.

After subtraction, the remaining input (received audio) is level adjusted by the remaining programmable potentiometer U15(1) exactly as in the four-wire case.

Analog switch U17 selects which filter stage output, if any, is routed to the transmitter. Depending upon the transmit frequency band, the FCC requires different filter characteristics for the post-limiter filter. The output of analog switch U17-B DSP TXAUD is routed to P2-7 where it connects to the System Module.

The RX output of U4 pin 2 DSPLINE/TXAUD is routed to P2-8 where it connect to the System Module. This audio output typically drives the line out circuits on the System Module.

The DSP Board is equipped with a full duplex, parallel interface for communications between the System Module microprocessor and the DSP microprocessor chip. Communications are accomplished through a dual port RAM, U12.

Byte-wide messages are passed between System Module and DSP chip by reading and writing data upon this common piece of memory.

The external eight-bit System microprocessor can read and write to the dual port RAM. A 74HC373 address latch (U13) is used by the 8-bit host to latch the address (AD7-AD0). The host uses its ALE signal to perform the actual clocking into the latch.

Once ALE has returned to logic one, AD7-AD0 become bi-directional data pins. During a "write" cycle, the host sets up data on AD7-AD0. During a "read" cycle, the System Module microprocessor releases the data lines AD7-AD0 into their high impedance state.

LBI-38764

DSP Analog Outputs

The Rx output of codec U5, TX CODEC RX, passes through U16-B for pre-emphasis and hard limiting. Limiting action occurs when the instantaneous AC voltage exceeds the DC bias set by R34, R36, and R37, at which point D1 becomes forward biased placing it in the feedback loop of U16-B. Due to the V-I characteristic of the diode, limiting action occurs. U16-B also provides +6 dB/octave pre-emphasis for transmitted audio in the 300 Hz to 3 kHz band. The pre-emphasis meets the EIA standard of +1/-3 gain flatness in its passband.

Following the pre-emphasis and limiter, U16-C forms a third order low pass filter stage required by FCC regulations to filter the harmonics created by the preceding limiter. R35 and C29 compose a passive first order low pass while active filter U16-C provides an additional two poles for this filter stage. Following U16-C is another filter stage consisting of a second order passive low pass and a second order active low pass built around U16-D.

Parallel Communications Hardware

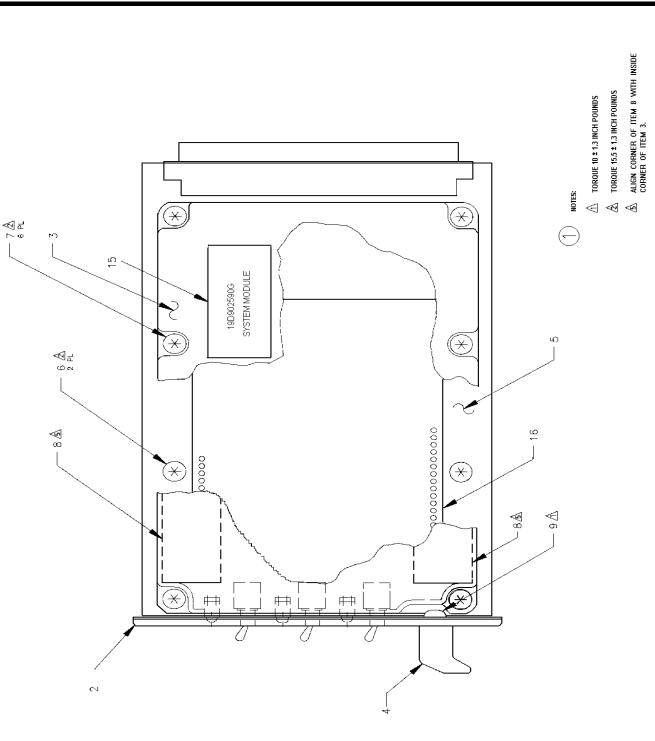
Finally, the System Module's low-going /UPRD or /**UPWR** pulse executes the desired read/write function. Note that reading and writing is only accomplished when the **DSP_CS** signal is held low. In this way, the System Module microprocessor exclusively selects the dual port memory space to prevent contention upon the multiplexed address and data bus.

The DSP chip reads and writes from the dual port RAM by first selecting its communication memory space. This is accomplished by setting A13-A11 to binary 010 when PMS goes low. Such a sequence will cause U8 pin 13 to go low and thus enable the dual port RAM, U12. Once enabled, the communications memory is accessed with address lines A9-A0 and data lines D15-D8, in conjunction with a low-going /RD or /WR pulse.

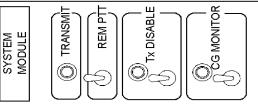
The DSP chip (U1) and host processor coordinate message handling through the **RBLE** and **TBLF** flags. The DSP chip sets **TBLF** by writing to location 3FFH of the dual port RAM; it clears **RBLE** by reading from location 3FEH of the dual port RAM.

Similarly, the host microprocessor can clear TBLF by reading from location 3FFH of the dual port RAM. It then sets **RBLE** by writing to location 3FEH of the dual port RAM. (Note that a flag is set when it is low; it is clear when it is high.) This way, both microprocessors can monitor flag conditions in order to keep from trying to access the same locations in memory at the same time.

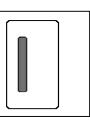
Tri-state buffer U9 is used by the DSP microprocessor in order to read the **RBLE** and **TBLF** flags. This alleviates the possibility of contention on the DSP's data bus D15-D8. The **RBLE** and **TBLF** flags are read by first selecting U9. This is accomplished by setting A13-A11 to binary 100 when /PMS goes low. Such a sequence will cause U8-pin 14 to go low and thus enable data to pass through the tri-state buffer upon /RD going low. U9, pins 2 and 3 appear on D8 and D9, and are latched into U1 when /RD returns high.







(19D902590, Sh. 1, Rev. 3)



SYSTEM MODULE

19D902590G1 - M IIe System Module 19D902590G2 - M IIe System Module with DSP 19D902590G3 - M III System Module with DSP

$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	SYMBOL	PART NO.	DESCRIPTION
$\begin{array}{ccccc} 4 & 19D902555P1 & Handle. \\ 19A702381P503 & Screw, thread forming: TORX, No. M3.5 - 0.6 x 6. \\ 7 & 19A702381P503 & Screw, thread forming: TORX, No. M3.5 - 0.6 x 13. \\ 8 & 19B232682P20 & Pad. (Used in G2 and G3). \\ 9 & 19A702381P508 & Screw, thread forming: No. 3.5 - 0.6 x 8. \\ 19D902667G1 & Digital Signal Processor, (Used in G2 and G3). \\ 18 & 19D903771G1 & System Board (See below). \\ & SYSTEM BOARD \\ 19D903771G1 & System Board (See below). \\ & SYSTEM BOARD \\ 19D903771G1 & Ceramic: 1000 pF \pm 10%, 50 VDCW. \\ C1 & 19A702052P5 & Ceramic: 1000 pF \pm 10%, 50 VDCW. \\ C2 & 19A702052P14 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C3 & 19A702052P26 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C4 & 19A702052P114 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C6 & 19A702052P26 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C6 & 19A702052P114 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C10 & 19A702052P114 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C11 & 19A702052P28 & Tantalum: 6.8 \mu F, 10 VDCW; sim to Sprague 293D. \\ C14 & 19A702052P214 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C15 & 19A702052P214 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C16 & 19A702052P14 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C16 & 19A702052P14 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C16 & 19A702052P24 & Ceramic: 0.068 \mu F \pm 5\%, 50 VDCW. \\ C16 & 19A702052P24 & Ceramic: 0.0068 \mu F \pm 1\%, 50 VDCW. \\ C17 & 19A702052P24 & Ceramic: 0.0068 \mu F \pm 10\%, 50 VDCW. \\ C21 & 19A702052P25 & Ceramic: 0.0068 \mu F \pm 10\%, 50 VDCW. \\ C21 & 19A702052P24 & Ceramic: 0.0068 \mu F \pm 10\%, 50 VDCW. \\ C22 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C23 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C24 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C25 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C26 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C38 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C38 & 19A702052P5 & Ceramic: 0.01 \mu F \pm 10\%, 50 VDCW. \\ C39 & 19A702052P5 & Tantalum: 10 \mu F, 16 VDCW; sim to Sprague 233D. \\ C40 & 19A70252P5 & Tantalum: 10 \mu F, 16 VDCW; sim to Sprague 233D. \\ C4$	2	19D902485P1	Chassis.
6 19A702381P506 Screw, thread forming: TORX, No. M3.5 - 0.6 x 6. 7 19A702381P508 Screw, thread forming: TORX, No. M3.5 - 0.6 x 13. 8 19B232682P20 Pad. (Used in G2 and G3). 9 19A702381P508 Screw, thread forming: No. 3.5 - 0.6 x 8. 15 19B235310P1 Nameplate. 16 19D902667G1 Digital Signal Processor, (Used in G2 and G3). 18 19D903771G1 System Board (See below). SYSTEM BOARD 19A702052P5 Ceramic: 1000 pF ±10%, 50 VDCW. Caramic: 1001 pF ± 5%, 50 VDCW. Ceramic: 1001 pF ± 5%, 50 VDCW. C3 19A702052P5 Ceramic: 1001 pF ± 10%, 50 VDCW. C4 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C5 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C6 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C1 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C1 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C11 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C11 19A702052P14 Ceramic: 0.01 µF ± 10%, 50 VDCW. C11 <td>3</td> <td>19D902486P1</td> <td>Cover.</td>	3	19D902486P1	Cover.
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$\begin{array}{ccccc} 9 & 19A702381P508 \\ 15 & 19B235310P1 \\ 16 & 19D902667G1 \\ 19D902667G1 \\ 19D903771G1 \\ 19D903771G1 \\ 19D903771G1 \\ \\ \hline $	7	19A702381P513	Screw, thread forming: TORX, No. M3.5 - 0.6 X 13.
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$ \begin{array}{cccccccccccccccccccccccccccccccccccc$			SYSTEM BOARD
$\begin{array}{cccc} 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C3 & 19A702051P13 & Ceramic: 100 \ pF \pm 10\%, 50 \ VDCW, temp \ coef 0 \pm 30 \ PPM/°C. \\ \hline C4 & 19A702052P26 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C5 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 5\%, 50 \ VDCW. \\ \hline C6 & 19A702052P114 & Ceramic: 0.01 \ \mu F \pm 5\%, 50 \ VDCW. \\ \hline C8 & 19A702052P28 & Ceramic: 0.01 \ \mu F \pm 5\%, 50 \ VDCW. \\ \hline C10 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C10 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C11 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C12 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C13 & 19A702052P14 & Ceramic: 0.068 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C14 & 19A702052P5 & Tantalum: 10 \ \mu F, 16 \ VDCW; sim to \ Sprague 293D. \\ \hline C15 & 19A702052P12 & Ceramic: 0.068 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C16 & 19A702052P2 & Ceramic: 0.008 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C17 & 19A702052P5 & Ceramic: 0.008 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C19 & 19A702052P2 & Ceramic: 0.008 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C21 & 19A702052P4 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C21 & 19A702052P5 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C22 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C23 & 19A702052P11 & 47 \ \mu F \pm 10\%, 10 \ VDCW; sim to \ Sprague 293D. \\ \hline C22 & 19A702052P5 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C23 & 19A702052P5 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C23 & 19A702052P5 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C33 & 19A702052P5 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ \hline C33 & 19A702052P5 & Tantalum: 10 \ \mu F, 16 \ VDCW; sim to \ Sprague 293D. \\ \hline C40 & 19A7025205P1 & Tantalum: 10 \ \mu F, 16 \ VDCW; sim to \ Sprague 293D. \\ \hline C40 & 19A7025205P6 & Tantalum: 10 \ \mu F, 16 \ VDCW; sim to \ Sprague 293D. \\ \hline C44 & 344A3431P1 & Monolithic: 1.0 \ \mu F + 80/-20\%, 16 \ VDCW. \\ \hline C46 & 344A3431P1 & Monolithic: 1.0 \ \mu F + 80/-20\%, 16 \ VDCW. \\ \hline C46 & 344A3431P1 & Monolithic: 1.0 \ \mu F + 80/-20\%, 16 \ VDCW. \\ \hline C46 & 344A3431P1 & Monolithic: 1.0 \ \mu F + 80/-20\%$			CAPACITORS
$ \begin{array}{ccccc} C3 & 19A702061P13 & Ceramic: 10 pF \pm 5\%, 50 VDCW, temp coef 0 \pm 30 \\ PPM/°C. \\ C4 & 19A702052P5 & Ceramic: 1000 pF \pm 10\%, 50 VDCW. \\ C5 & 19A702052P21 & Ceramic: 0.1 \muF \pm 10\%, 50 VDCW. \\ C6 & 19A702052P114 & Ceramic: 0.01 \muF \pm 5\%, 50 VDCW. \\ C7 & 19A702052P28 & Ceramic: 0.022 \muF \pm10\%, 50 VDCW. \\ C10 & 19A702052P14 & Ceramic: 0.01 \muF \pm 5\%, 50 VDCW. \\ C11 & 19A702052P14 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C12 & 19A702052P14 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C13 & 19A702052P14 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C14 & 19A702052P14 & Ceramic: 0.068 \muF \pm 5\%, 50 VDCW. \\ C15 & 19A702052P12 & Ceramic: 0.068 \muF \pm 5\%, 50 VDCW. \\ C16 & 19A702052P5 & Ceramic: 0.068 \muF \pm 10\%, 50 VDCW. \\ C17 & 19A702052P5 & Ceramic: 0.0068 \muF \pm 10\%, 50 VDCW. \\ C18 & 19A702052P5 & Ceramic: 0.008 \muF \pm 10\%, 50 VDCW. \\ C21 & 19A702052P5 & Ceramic: 0.008 \muF \pm 10\%, 50 VDCW. \\ C21 & 19A702052P5 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C21 & 19A702052P5 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C22 & 19A702052P1 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C23 & 19A702052P14 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C25 & 19A702052P11 & 47 \muF \pm 10\%, 10VDCW; sim to Sprague 293D. \\ C22 & 19A702052P5 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C23 & 19A702052P11 & 47 \muF \pm 10\%, 10VDCW; sim to Sprague 293D. \\ C43 & 19A702052P5 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C33 & 19A702052P5 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C33 & 19A702052P5 & Ceramic: 0.01 \muF \pm 10\%, 50 VDCW. \\ C33 & 19A702052P5 & Tantalum: 10 \muF, 16 VDCW; sim to Sprague 293D. \\ C44 & 344A3431P1 & Monolithic: 1.0 \muF \pm 80/-20\%, 16 VDCW. \\ C46 & 344A3431P1 & Monolithic: 1.0 \muF \pm 5\%, 50 VDCW. \\ C46 & 344A3431P1 & Monolithic: 1.0 \muF \pm 5\%, 50 VDCW. \\ C46 & 344A3431P1 & Monolithic: 1.0 \muF \pm 5\%, 50 VDCW. \\ C46 & 344A3431P1 & Monolithic: 1.0 \muF \pm 5\%, 50 VDCW. \\ C46 & 344A3431P1 & Monolithic: 1.0 \muF \pm 5\%, 50 VDCW. \\ C47 & 19A702052P114 & Ceramic: 0.01 \muF \pm 5\%, 50 VDCW. \\ C46 & 344A3431P1 & Monol$	C1	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
C419A702052P5Ceramic: 100 pF \pm 10%, 50 VDCW.C519A702052P26Ceramic: 0.1 µF \pm 10%, 50 VDCW.C619A702052P114Ceramic: 0.1 µF \pm 5%, 50 VDCW.C719A702052P14Ceramic: 0.01 µF \pm 5%, 50 VDCW.C819A702052P28Ceramic: 0.022 µF \pm 10%, 50 VDCW.C1019A702052P14Ceramic: 0.01 µF \pm 5%, 50 VDCW.C1119A702052P14Ceramic: 0.01 µF \pm 10%, 50 VDCW.C1219A702052P14Ceramic: 0.01 µF \pm 10%, 50 VDCW.C1319A702052P14Ceramic: 0.01 µF \pm 10%, 50 VDCW.C1419A702052P12Tantalum: 1 µF, 16 VDCW; sim to Sprague 293D.C1519A702052P12Ceramic: 0.068 µF \pm 5%, 50 VDCW.C1619A702052P2Tantalum: 1 µF, 16 VDCW; sim to Sprague 293D.C1819A702052P2Ceramic: 1000 pF \pm 10%, 50 VDCW.C1919A702052P2Ceramic: 1000 pF \pm 10%, 50 VDCW.C2119A702052P14Ceramic: 0.01 µF \pm 10%, 50 VDCW.C2219A702052P14Ceramic: 0.1 µF \pm 10%, 50 VDCW.C2319A702052P14Ceramic: 0.1 µF \pm 10%, 50 VDCW.C2519A705205P11147 µF \pm 10%, 10VDCW; sim to SpragueC3619A702052P5Ceramic: 0.01 µF \pm 10%, 50 VDCW.C3819A702052P54Ceramic: 0.01 µF \pm 10%, 50 VDCW.C3819A702052P56Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.C4119A705205P6Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: 10 µ	C2	19A702052P14	Ceramic: 0.01 $\mu\text{F}\pm$ 10%, 50 VDCW.
C519A702052P26Ceramic: $0.1 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C619A702052P114Ceramic: $0.01 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}.$ C719A702052P18Tantalum: $6.8 \ \mu\text{F}, 10 \ \text{VDCW}; \text{ sim to Sprague 293D}.$ C919A702052P28Ceramic: $0.022 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C1019A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}.$ C1119A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}.$ C1219A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C1319A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C1419A705205P2Tantalum: $1 \ \mu\text{F}, 16 \ \text{VDCW}; \text{ sim to Sprague 293D}.$ C1519A702052P5Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C1619A702052P24Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C1919A702052P24Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C2119A702052P5Ceramic: $0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C2219A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C2319A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C2319A702052P5Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C3619A702052P5Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C3819A702052P5Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C3919A702052P5Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C4019A705205P6Tantalum: $10 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}.$ C4119A702052P5Ceramic: $1000 \ \text{p} \pm 10\%, 50 \ \text{VDCW}.$ C4219A702052P	C3	19A702061P13	
$\begin{array}{ccccc} & 19A702052P114 \\ \text{Geramic: } 0.01 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C7} \\ \text{C8} \\ 19A702052P58 \\ \text{C9} \\ 19A702052P28 \\ \text{C9} \\ 19A702052P14 \\ \text{Ceramic: } 0.022 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C10} \\ 19A702052P14 \\ \text{Ceramic: } 0.01 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C11} \\ 19A702052P14 \\ \text{Ceramic: } 0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C13} \\ 19A705205P2 \\ \text{C14} \\ 19A702052P124 \\ \text{Ceramic: } 0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C13} \\ 19A702052P124 \\ \text{Ceramic: } 0.068 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C16} \\ 19A702052P5 \\ \text{Caramic: } 1000 \ \text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C17} \\ 19A702052P5 \\ \text{C18} \\ 19A702052P24 \\ \text{Ceramic: } 1000 \ \text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C19} \\ 19A702052P5 \\ \text{Ceramic: } 1000 \ \text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C21} \\ 19A702052P5 \\ \text{C22} \\ 19A702052P5 \\ \text{Ceramic: } 0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C23} \\ 19A702052P5 \\ \text{Ceramic: } 0.1 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C23} \\ 19A702052P14 \\ \text{Ceramic: } 0.1 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C23} \\ 19A702052P5 \\ \text{Ceramic: } 0.1 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C23} \\ 19A702052P5 \\ \text{Ceramic: } 1000 \ \text{pF} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C24} \\ 19A702052P5 \\ \text{Ceramic: } 1000 \ \text{pF} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C25} \\ 19A702052P5 \\ \text{Ceramic: } 1000 \ \text{pF} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \text{C38} \\ 19A702052P5 \\ \text{Ceramic: } 1000 \ \text{pF} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \hline \\ \text{C38} \\ 19A702052P5 \\ \text{Caramic: } 1000 \ \text{pF} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \hline \\ \text{C41} \\ 19A705205P6 \\ \text{Tantalum: } 0.4 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \hline \\ \text{C41} \\ 19A705205P6 \\ \text{Caramic: } 0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \hline \\ \hline \\ \ \\ \end{tabular} 10 \ \mu\text{F} 16 \ \text{VDCW}; \ \text{sim to } \text{Sprague } 293D. \\ \hline \\ \hline \\ \ \\ \begin{tabular}{caramic} 19A705205P6 \\ \text{Tantalum: } 10 \ \mu\text{F} 16 \ \text{VDCW}; \ \text{sim to } \text{Sprague } 293D. \\ \hline \\ \hline \\ \end{tabular} 10 \ \mu\text{F} 16 \ \text{VDCW}; \ \text{sim to } \text{Sprague } 293D. \\ \hline \\ \hline \\ \ \ \\ \end{tabular} 10 \ \mu\text{F} 16 \ \text{VDCW}; \ \text{sim to } \text{Sprague } 293D. \\ \hline \\ \hline \\ \ \ \ \$	C4	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
$\begin{array}{ccccc} and \\ C7 \\ C8 \\ 19A705205P5 \\ C9 \\ 19A702052P28 \\ Ceramic: 0.022 \ \mu F \pm 10\%, 50 \ VDCW. \\ C10 \\ 19A702052P114 \\ Ceramic: 0.01 \ \mu F \pm 5\%, 50 \ VDCW. \\ C11 \\ C12 \\ 19A702052P14 \\ Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ C13 \\ 19A705205P2 \\ Tantalum: 1 \ \mu F, 16 \ VDCW; sim to Sprague 293D. \\ C14 \\ 19A705205P2 \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague 293D. \\ C15 \\ 19A702052P124 \\ Ceramic: 0.068 \ \mu F \pm 5\%, 50 \ VDCW. \\ C16 \\ 19A702052P5 \\ C17 \\ 19A702052P5 \\ C17 \\ 19A702052P2 \\ C18 \\ 19A702052P2 \\ C18 \\ 19A702052P5 \\ C19 \\ 19A702052P5 \\ C19 \\ 19A702052P5 \\ C21 \\ 19A702052P5 \\ C22 \\ 19A702052P14 \\ Ceramic: 0.068 \ \mu F \pm 10\%, 50 \ VDCW. \\ C23 \\ 19A702052P14 \\ Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ C25 \\ 19A702052P14 \\ Ceramic: 0.1 \ \mu F \pm 10\%, 50 \ VDCW. \\ C25 \\ 19A702052P14 \\ Ceramic: 0.1 \ \mu F \pm 10\%, 50 \ VDCW. \\ C25 \\ 19A702052P14 \\ Ceramic: 0.1 \ \mu F \pm 10\%, 50 \ VDCW. \\ C25 \\ 19A702052P11 \\ 47 \ \mu F \pm 10\%, 10 \ VDCW; sim to Sprague \\ 47 \ \mu F \pm 10\%, 10 \ VDCW; sim to Sprague \\ 47 \ \mu F \pm 10\%, 10 \ VDCW; sim to Sprague \\ 229 \\ 19A702052P5 \\ Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ C38 \\ 19A702052P5 \\ Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ C38 \\ 19A702052P5 \\ Caramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 239 \\ C40 \\ 19A705205P5 \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16 \ VDCW; sim to Sprague \\ 230. \\ Tantalum: 10 \ \mu F, 16$	C5	19A702052P26	Ceramic: 0.1 $\mu\text{F}\pm$ 10%, 50 VDCW.
C819A705205P5 19A702052P28Tantalum: 6.8μ F, 10 VDCW; sim to Sprague 293D.C919A702052P18Ceramic: 0.022μ F ±10%, 50 VDCW.C1019A702052P114Ceramic: 0.01μ F ±5%, 50 VDCW.C1219A702052P14Ceramic: 0.01μ F ± 10%, 50 VDCW.C1319A705205P2Tantalum: 1μ F, 16 VDCW; sim to Sprague 293D.C1419A705205P6Tantalum: 10μ F, 16 VDCW; sim to Sprague 293D.C1519A702052P124Ceramic: 0.068μ F ± 5%, 50 VDCW.C1619A702052P5Ceramic: $1000 p$ F ±10%, 50 VDCW.C1719A702052P24Ceramic: 0.068μ F ± 10%, 50 VDCW.C1819A702052P24Ceramic: 0.008μ F ± 10%, 50 VDCW.C2119A702052P5Ceramic: 0.01μ F ±10%, 50 VDCW.C2219A702052P14Ceramic: 0.01μ F ±10%, 50 VDCW.C2319A702052P14Ceramic: 0.01μ F ±10%, 50 VDCW.C2419A702052P11147 μ F ±10%, 10VDCW; sim to SpragueC2519A702052P51Ceramic: 0.01μ F ±10%, 50 VDCW.C2619A705205P11147 μ F ±10%, 10VDCW; sim to SpragueC2719A702052P54Ceramic: 0.01μ F ±10%, 50 VDCW.C3819A702052P54Ceramic: 0.01μ F ±10%, 50 VDCW.C3919A705205P6Tantalum: 10μ F, 16 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: 10μ F, 16 VDCW; sim to Sprague 293D.C4119A705205P6Tantalum: 10μ F, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: 10μ F, 16 VDCW; sim to Sprague 293D.C4419	and	19A702052P114	Ceramic: 0.01 $\mu\text{F}\pm$ 5%, 50 VDCW.
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		19A705205P5	Tantalum: 6.8 uF 10 V/DCW/: cim to Sprague 202D
C10 and C1119A702052P114Ceramic: $0.01 \ \mu\text{F} \pm 5\%$, 50 VDCW.C11 C1219A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C13 C1419A705205P2Tantalum: $1 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C14 C15 C1719A702052P124Ceramic: $0.068 \ \mu\text{F} \pm 5\%$, 50 VDCW.C16 C19A702052P519A702052P5Ceramic: $0.006 \ \mu\text{F} \pm 10\%$, 50 VDCW.C17 C19A705205P2 C1819A702052P52Ceramic: $0.006 \ \mu\text{F} \pm 10\%$, 50 VDCW.C19 C19 C19A702052P519A702052P5Ceramic: $0.00 \ \mu\text{F} \pm 10\%$, 50 VDCW.C21 C21 D4702052P5419A702052P54Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C22 C23 C24 D4705205P111Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C25 C25 D4705205P111 D4705205P111Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C25 C26 C27 D4705205P111 A705205P5Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C38 C29 T9A705205P5111 C40 D4705205P6Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C38 C42 T9A705205P619A702052P54C43 C44 T9A705205P6Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C44 T9A705205P6 Tantalum: $10 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C42 T9A705205P6Tantalum: $10 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C44 T9A705205P6Tantalum: $10 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C45 C46 C46 C44 C47 T9A702052P114Monolithic: $1.0 \ \mu\text{F}$ +80/-20%, 16 VDCW.C47 C47 T9A702052P114Monolithic: $1.0 \ \mu\text{F} \pm 5\%$, 50 VDCW.			
$ \begin{array}{ccccc} and \\ c11 \\ c12 \\ c13 \\ c13 \\ c14 \\ c13 \\ c14 \\ c13 \\ c14 \\ c13 \\ c14 \\ c14 \\ c13 \\ c14 \\ c15 \\ c15 \\ c15 \\ c15 \\ c15 \\ c15 \\ c16 \\ $			•
C1319A705205P2Tantalum: 1 μ F, 16 VDCW; sim to Sprague 293D.C1419A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C1519A702052P124Ceramic: 0.068 μ F ± 5%, 50 VDCW.C1619A702052P5Ceramic: 1000 PF ±10%, 50 VDCW.C1719A705205P2Tantalum: 1 μ F, 16 VDCW; sim to Sprague 293D.C1819A702052P4Ceramic: 0.068 μ F ± 10%, 50 VDCW.C1919A702052P5Ceramic: 1000 PF ±10%, 50 VDCW.C2119A702052P5Ceramic: 1000 PF ± 10%, 50 VDCW.C2219A702052P14Ceramic: 0.01 μ F ± 10%, 50 VDCW.C2319A702052P14Ceramic: 0.1 μ F ± 10%, 50 VDCW.C2519A705205P11147 μ F ±10%, 10VDCW; sim to SpragueC2719A705205P11147 μ F ±10%, 10VDCW; sim to SpragueC2819A702052P5Ceramic: 0.01 μ F ±10%, 50 VDCW.C3819A702052P5Ceramic: 0.01 μ F ±10%, 50 VDCW.C3919A705205P61Tantalum: 6.8 μ F, 10 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C4419A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C45344A3431P1Monolithic: 1.0 μ F +80/-20%, 16 VDCW.C4719A702052P114Ceramic: 0.01 μ F ±5%, 50 VDCW.	and	19A702052F114	Ceramic. 0.01 μ F ± 5%, 50 VDCW.
C1419A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C1519A702052P124Ceramic: 0.068 μ F ±5%, 50 VDCW.C1619A702052P5Ceramic: 1000 pF ±10%, 50 VDCW.C1719A705205P2Tantalum: 1 μ F, 16 VDCW; sim to Sprague 293D.C1819A702052P4Ceramic: 1000 pF ±10%, 50 VDCW.C1919A702052P5Ceramic: 1000 pF ±10%, 50 VDCW.C2119A702052P5Ceramic: 1000 pF ±10%, 50 VDCW.C2119A702052P14Ceramic: 0.01 μ F ± 10%, 50 VDCW.C2319A702052P26Ceramic: 0.01 μ F ± 10%, 50 VDCW.C2319A705205P11147 μ F ±10%, 10VDCW; sim to SpragueC2419A705205P11147 μ F ±10%, 10VDCW; sim to SpragueC2819A702052P5Ceramic: 0.01 μ F ±10%, 50 VDCW.C3819A702052P5Ceramic: 0.01 μ F ±10%, 50 VDCW.C3819A702052P5Tantalum: 6.8 μ F, 10 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C4419A705205P6Tantalum: 10 μ F, 16 VDCW; sim to Sprague 293D.C45344A3431P1Monolithic: 1.0 μ F +80/-20%, 16 VDCW.C4719A702052P114Ceramic: 0.01 μ F ±5%, 50 VDCW.	C12	19A702052P14	Ceramic: 0.01 μ F ± 10%, 50 VDCW.
C1519A702052P124Ceramic: $0.068 \ \mu\text{F} \pm 5\%$, 50 VDCW.C1619A702052P5Ceramic: $1000 \ \text{pF} \pm 10\%$, 50 VDCW.C1719A705205P2Tantalum: $1 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C1819A702052P24Ceramic: $0.068 \ \mu\text{F} \pm 10\%$, 50 VDCW.C1919A702052P5Ceramic: $0.068 \ \mu\text{F} \pm 10\%$, 50 VDCW.C2119A702052P5Ceramic: $0.068 \ \mu\text{F} \pm 10\%$, 50 VDCW.C2119A702052P5Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C2219A702052P14Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C2319A702052P26Ceramic: $0.1 \ \mu\text{F} \pm 10\%$, 50 VDCW.C2519A705205P11147 \ \mu\text{F} \pm 10\%, $10VDCW$; sim to SpragueC2719A705205P11147 \ \mu\text{F} \pm 10\%, $10VDCW$; sim to SpragueC2819A702052P5Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C3819A702052P5Ceramic: $0.01 \ \mu\text{F} \pm 10\%$, 50 VDCW.C3919A705205P61Tantalum: $6.8 \ \mu\text{F}$, 10 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: $10 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: $10 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: $10 \ \mu\text{F}$, 16 VDCW; sim to Sprague 293D.C4219A702052P114Monolithic: $1.0 \ \mu\text{F} + 80/-20\%$, 16 VDCW.C4719A702052P114Ceramic: $0.01 \ \mu\text{F} \pm 5\%$, 50 VDCW.C4719A702052P114Ceramic: $0.01 \ \mu\text{F} \pm 5\%$, 50 VDCW.	C13	19A705205P2	Tantalum: 1 µF, 16 VDCW; sim to Sprague 293D.
C1619A702052P5Ceramic: 1000 pF $\pm 10\%$, 50 VDCW.C1719A705205P2Tantalum: 1 µF, 16 VDCW; sim to Sprague 293D.C1819A702052P24Ceramic: 0.068 µF $\pm 10\%$, 50 VDCW.C1919A702052P5Ceramic: 0.068 µF $\pm 10\%$, 50 VDCW.C2119A702052P4Ceramic: 1000 pF $\pm 10\%$, 50 VDCW.C2219A702052P14Ceramic: 0.01 µF $\pm 10\%$, 50 VDCW.C2319A702052P26Ceramic: 0.01 µF $\pm 10\%$, 50 VDCW.C2319A702052P14Ceramic: 0.1 µF $\pm 10\%$, 50 VDCW.C2519A705205P11147 µF $\pm 10\%$, 10VDCW; sim to SpragueC2719A705205P11147 µF $\pm 10\%$, 10VDCW; sim to SpragueC2819A702052P5Ceramic: 0.01 µF $\pm 10\%$, 50 VDCW.C3819A702052P5Ceramic: 0.01 µF $\pm 10\%$, 50 VDCW.C3919A705205P61Tantalum: 6.8 µF, 10 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.C4419A705205P6Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.C45344A3431P1Monolithic: 1.0 µF +80/-20\%, 16 VDCW.C4719A702052P114Ceramic: 0.01 µF $\pm 5\%$, 50 VDCW.	C14	19A705205P6	Tantalum: 10 µF, 16 VDCW; sim to Sprague 293D.
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	C15	19A702052P124	Ceramic: 0.068 μF ± 5%, 50 VDCW.
C1819A702052P24Ceramic: $0.068 \ \mu F \pm 10\%$, 50 VDCW.C1919A702052P5Ceramic: $1000 \ pF \pm 10\%$, 50 VDCW.C2119A702061P77Ceramic: $470 \ pF \pm 5\%$, 50 VDCW, temp coef 0 ± 30 C2219A702052P14Ceramic: $0.1 \ \mu F \pm 10\%$, 50 VDCW.C2319A702052P26Ceramic: $0.1 \ \mu F \pm 10\%$, 50 VDCW.C2519A705205P11147 \ \mu F \pm 10\%, 10VDCW; sim to SpragueC2719A705205P11147 \ \mu F \pm 10\%, 10VDCW; sim to SpragueC2819A702052P5Ceramic: $1000 \ pF \pm 10\%$, 50 VDCW.C2919A702052P5Ceramic: $1000 \ pF \pm 10\%$, 50 VDCW.C3819A702052P5Ceramic: $0.01 \ \mu F \pm 10\%$, 50 VDCW.C3819A705205P6Tantalum: $6.8 \ \mu F$, 10 VDCW; sim to Sprague 293D.C4019A705205P6Tantalum: $10 \ \mu F$, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: $10 \ \mu F$, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: $10 \ \mu F$, 16 VDCW; sim to Sprague 293D.C4219A705205P6Tantalum: $10 \ \mu F$, 16 VDCW; sim to Sprague 293D.C44344A3431P1Monolithic: $1.0 \ \mu F$ +80/-20%, 16 VDCW.C4719A702052P114Ceramic: $0.01 \ \mu F \pm 5\%$, 50 VDCW.	C16	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	C17	19A705205P2	Tantalum: 1 µF, 16 VDCW; sim to Sprague 293D.
$ \begin{array}{cccccc} C21 & 19A702061P77 & Ceramic: 470 \ pF \pm 5\%, 50 \ VDCW, \ temp \ coef \ 0 \pm 30 \ PPM/^{\circ}C. \\ \hline \\ C22 & 19A702052P14 & Ceramic: 0.1 \ \muF \pm 10\%, 50 \ VDCW. \\ \hline \\ C23 & 19A702052P26 & Ceramic: 0.1 \ \muF \pm 10\%, 50 \ VDCW. \\ \hline \\ C25 & 19A705205P111 & 47 \ \muF \pm 10\%, 10VDCW; \ sim \ to \ Sprague \\ \hline \\ C27 & 19A705205P111 & 47 \ \muF \pm 10\%, 10VDCW; \ sim \ to \ Sprague \\ \hline \\ C28 & C29 & 19A702052P5 & Ceramic: 1000 \ pF \pm 10\%, 50 \ VDCW. \\ \hline \\ C38 & 19A702052P5 & Ceramic: 0.01 \ \muF \pm 10\%, 50 \ VDCW. \\ \hline \\ C38 & 19A705205P1 & Ceramic: 0.01 \ \muF \pm 10\%, 50 \ VDCW. \\ \hline \\ C39 & 19A705205P5 & Tantalum: 6.8 \ \muF, 10 \ VDCW; \ sim \ to \ Sprague \ 293D. \\ \hline \\ C40 & 19A705205P6 & Tantalum: 10 \ \muF, 16 \ VDCW; \ sim \ to \ Sprague \ 293D. \\ \hline \\ C42 & 19A705205P6 & Tantalum: 10 \ \muF, 16 \ VDCW; \ sim \ to \ Sprague \ 293D. \\ \hline \\ C42 & thru \\ C45 & C46 & 344A3431P1 & Monolithic: 1.0 \ \muF + 80/-20\%, 16 \ VDCW. \\ \hline \\ C47 & 19A702052P114 & Ceramic: 0.01 \ \muF \pm 5\%, 50 \ VDCW. \\ \hline \\ \end{array}$	C18	19A702052P24	Ceramic: 0.068 μF ± 10%, 50 VDCW.
$\begin{array}{ccccccc} & \mbox{PPM/}{}^{\circ}\mbox{C}. \\ \mbox{C22} & 19A702052P14 & \mbox{Ceramic: } 0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \mbox{C23} & 19A702052P26 & \mbox{Ceramic: } 0.1 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \mbox{C25} & 19A705205P111 & 47 \ \mu\text{F} \pm 10\%, 10 \ \text{VDCW}; \ \mbox{sin to Sprague} \\ \mbox{C27} & 19A705205P111 & 47 \ \mu\text{F} \pm 10\%, 10 \ \text{VDCW}; \ \mbox{sin to Sprague} \\ \mbox{C28} & \mbox{C29} & 19A702052P5 & \mbox{Ceramic: } 1000 \ \text{PF} \pm 10\%, 50 \ \text{VDCW}. \\ \mbox{C38} & 19A702052P5 & \mbox{Ceramic: } 0.01 \ \mu\text{F} \pm 10\%, 50 \ \text{VDCW}. \\ \mbox{C39} & 19A705205P6 & \mbox{Tantalum: } 6.8 \ \mu\text{F}, 10 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{C40} & 19A705205P6 & \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{C42} & 19A705205P6 & \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \mbox{sin to Sprague } 293D. \\ \mbox{Tantalum: } 10 \ \mu\text{F}, 16 \ \text{VDCW}. \\ \mbox{C45} & \mbox{S44A3431P1} & \mbox{Monolithic: } 1.0 \ \mu\text{F} + 80/-20\%, 16 \ \text{VDCW}. \\ \mbox{C47} & 19A702052P114 & \mbox{Ceramic: } 0.01 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \mbox{C47} & \mbox{Tantalum: } 10 \ \mu\text{F} \pm 5\%, 50 \ \text{VDCW}. \\ \$	C19	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	C21	19A702061P77	
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	C22	19A702052P14	Ceramic: 0.01 $\mu\text{F}\pm$ 10%, 50 VDCW.
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	C23	19A702052P26	Ceramic: 0.1 $\mu\text{F}\pm$ 10%, 50 VDCW.
$ \begin{array}{c} \text{and} \\ \text{C28} \\ \text{C29} \\ \text{thru} \\ \text{C36} \\ \text{C38} \\ \text{C38} \\ \text{19A702052P5} \\ \text{thru} \\ \text{C36} \\ \text{C38} \\ \text{19A702052P14} \\ \text{Ceramic: } 1000 \text{ pF} \pm 10\%, 50 \text{ VDCW.} \\ \text{C39} \\ \text{19A705205P5} \\ \text{Tantalum: } 6.8 \mu\text{F}, 10 \text{ VDCW}; \text{ sim to Sprague 293D.} \\ \text{C40} \\ \text{19A705205P6} \\ \text{C42} \\ \text{19A705205P6} \\ \text{C42} \\ \text{19A705205P6} \\ \text{C43} \\ \text{c44} \\ \text{c45} \\ \text{c46} \\ \text{344A3431P1} \\ \text{Monolithic: } 1.0 \mu\text{F}, 16 \text{ VDCW}; \text{ sim to Sprague 293D.} \\ \text{C47} \\ \text{19A702052P114} \\ \text{Ceramic: } 0.01 \mu\text{F} \pm 80/-20\%, 16 \text{ VDCW.} \\ \text{Ceramic: } 0.01 \mu\text{F} \pm 5\%, 50 \text{ VDCW.} \\ \end{array} $	C25	19A705205P111	47 µF ±10%, 10VDCW; sim to Sprague
	and	19A705205P111	47 μF ±10%, 10VDCW; sim to Sprague
$ \begin{array}{cccccc} C38 & 19A702052P14 & Ceramic: 0.01 \ \mu F \pm 10\%, 50 \ VDCW. \\ C39 & 19A705205P5 & Tantalum: 6.8 \ \mu F, 10 \ VDCW; sim to \ Sprague 293D. \\ C40 & 19A705205P6 & Tantalum: 10 \ \mu F, 16 \ VDCW; sim to \ Sprague 293D. \\ C42 & 19A705205P6 & Tantalum: 10 \ \mu F, 16 \ VDCW; sim to \ Sprague 293D. \\ C42 & thru \\ C45 & C46 & 344A3431P1 & Monolithic: 1.0 \ \mu F + 80/-20\%, 16 \ VDCW. \\ C47 & 19A702052P114 & Ceramic: 0.01 \ \mu F \pm 5\%, 50 \ VDCW. \\ \end{array} $	C29	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
$ \begin{array}{cccc} C39 & 19A705205P5 \\ C40 & 19A705205P6 \\ C42 & 19A705205P6 \\ C42 \\ thru \\ C45 \\ C46 & 344A3431P1 \\ C47 & 19A702052P114 \\ C50 \\ \end{array} \begin{array}{c} Tantalum: 6.8 \ \mu\text{F}, 10 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ Tantalum: 10 \ \mu\text{F}, 16 \ VDCW; sim to \ Sprague \ 293D. \\ C46 & 344A3431P1 \\ C47 & 19A702052P114 \\ C47 & Ceramic: 0.01 \ \mu\text{F} \ \pm5\%, 50 \ VDCW. \\ \end{array}$			
$ \begin{array}{cccc} C40 & 19A705205P6 \\ C42 & 19A705205P6 \\ thru \\ C45 \\ C46 & 344A3431P1 \\ C47 & 19A702052P114 \\ C50 \\ \end{array} \begin{array}{c} Tantalum: 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \text{sim to Sprague 293D}. \\ Tantalum: 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \text{sim to Sprague 293D}. \\ Tantalum: 10 \ \mu\text{F}, 16 \ \text{VDCW}; \ \text{sim to Sprague 293D}. \\ \end{array} $			
			Tantalum: 6.8 µF, 10 VDCW; sim to Sprague 293D.
$ \begin{array}{ccc} C46 & 344A3431P1 & {\mbox{Monolithic: } 1.0 \ \mu F \ +80/-20\%, \ 16 \ VDCW.} \\ C47 & 19A702052P114 & {\mbox{Ceramic: } 0.01 \ \mu F \ \pm5\%, \ 50 \ VDCW.} \\ thru \\ C50 & {\mbox{Common states}} \end{array} $	thru	19A705205P6	Tantalum: 10 $\mu\text{F},$ 16 VDCW; sim to Sprague 293D.
C47 19A702052P114 Ceramic: 0.01 μF ±5%, 50 VDCW. thru C50		344A3431P1	Monolithic: 1.0 uE +80/-20% 16 \/DC\//
thru C50			•
	thru		Coramio. 0.01 μr ±070, 00 VDOVV.
C51 19A702052P14 Ceramic: 0.01 μF ±10%, 50 VDCW.			
	C51	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
C52 19A702061P37 Ceramic: 33 pF \pm 5%, 50 VDCW, temp coef 0 \pm 30 PPM/°C.	C52	19A702061P37	

	PART NO	DESCRIPTION
C53	19A702061P45	Ceramic: 47 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.
C58	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
C59	19A702052P122	Ceramic: 0.047 μF ±5%, 50 VDCW.
and		
C60	404700050000	
C61	19A702052P26	Ceramic: 0.1 μ F ± 10%, 50 VDCW.
C62 thru	19A149791P1	Metallized Polyproylene: 0.022 ±1%, 100 VDCW.
C67		
C68	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
thru C71		
C72	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
and	13/10/20021 0	Ceramic. 1000 pr ±10%, 30 VDCW.
C73		
C74	19A702052P14	Ceramic: 0.01 μF ±5%, 50 VDCW.
thru C78		
C79	19A702052P114	Ceramic: 0.01 µF ±5%, 50 VDCW.
C80	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
thru		
C84		
C87 thru	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
C95		
C96	19A702052P14	Ceramic: 0.01 µF ±10%, 50 VDCW.
thru		
C98	40470005005	
C99	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
C100 and	19A702052P14	Ceramic: 0.01 $\mu\text{F}\pm$ 10%, 50 VDCW.
C101		
C102	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
C103	19A702052P114	Ceramic: 0.01 μF ±5%, 50 VDCW.
C104	19A705205P111	47 μF \pm 10%, 10 VDCW; sim to Sprague
C105	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
hru C108		
C109	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
and	13/11 020321 14	
C110		
C111	19A702052P114	Ceramic: 0.01 μF ±5%, 50 VDCW.
C112	19A702061P77	Ceramic: 470 pF \pm 5%, 50 VDCW, temp coef 0 \pm 30
C113	19A702052P114	
5115	19A702032F114	Ceramic: 0.01 $\mu\text{F}\pm$ 5%, 50 VDCW.
		DIODES
D1	19A700053P2	Silicon: 2 Diodes in Series; sim to BAV99.
hru วิช		
36		
	104702505040	
DS1 thru	19A703595P10	Diode, Optoelectric: Red; sim to HP HLMP-1301- 010.
DS3		
		JACKS
J1	19B801587P7	Connector, DIN: 96 male contacts, right angle mount-
J1	19B801587P7	Connector, DIN: 96 male contacts, right angle mount- ing; sim to AMP 650887-1.
J2	19B801587P7 19A704852P334	
J2 and		ing; sim to AMP 650887-1.
J2 and		ing; sim to AMP 650887-1. Connector, printed wire board.
J2 and J3	19A704852P334	ing; sim to AMP 650887-1. Connector, printed wire board.
J2 and J3 _1		ing; sim to AMP 650887-1. Connector, printed wire board.
J2 and J3 L1 and	19A704852P334	ing; sim to AMP 650887-1. Connector, printed wire board.
J2 and J3 L1 and	19A704852P334	ing; sim to AMP 650887-1. Connector, printed wire board.
J2 and J3 L1 and L2	19A704852P334 19A705470P53	ing; sim to AMP 650887-1. Connector, printed wire board. INDUCTORS Coil, fixed.
J2 and J3 L1 and L2 Q2	19A704852P334	ing; sim to AMP 650887-1. Connector, printed wire board. INDUCTORS Coil, fixed.
J1 J2 and J3 L1 and L2 Q2 Q4 and	19A704852P334 19A705470P53 19A700076P2	ing; sim to AMP 650887-1. Connector, printed wire board. INDUCTORS Coil, fixed.
J2 and J3 L1 and L2 Q2 Q4	19A704852P334 19A705470P53 19A700076P2	Connector, printed wire board. INDUCTORS Coil, fixed. TRANSISTORS Silicon, NPN: sim to MMBT3904, low profile.

SYN	IBOL	PART NO.	DESCRIPTION	
Q7	7	19A700076P2	Silicon, NPN: sim to MMBT3904, low profile.	
Q8		19A700059P2	Silicon, PNP: sim to MMBT3906, low profile.	
Q9		19A700076P2	Silicon, NPN: sim to MMBT3904, low profile.	
and	d			
Q1	0			
Q1		19A700059P2	Silicon, PNP: sim to MMBT3906, low profile.	
an Q1				
QI	2		250107020	
_			RESISTORS	
R1		19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R2		19B800607P473	Metal film: 47K ohms ±5%, 1/8 w.	
R3	3	19A702931P301	Metal film: 10K ohms ±1%, 200 VDCW, 1/8 w.	
R4	Ļ	19B800607P153	Metal film: 15K ohms ±5%, 1/8 w.	
R5	5	19B800607P332	Metal film: 3.3K ohms ±5%, 1/8 w.	
R6	5	19A702931P301	Metal film: 10K ohms ±1%, 200 VDCW, 1/8 w.	
R7	,	19A702931P249	Metal film: 3160 ohms ±1%, 200 VDCW, 1/8 w.	
R8	3	19A702931P313	Metal film: 13.3K ohms ±1%, 200 VDCW, 1/8 w.	
R9	,	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R1	0	19B800607P391	Metal film: 390 ohms ±5%, 1/8 w.	
R1		19B800607P562	Metal film: 5.6K ohms ±5%, 1/8 w.	
R1		19B800607P103	Metal film: 10K ohms \pm 5%, 1/8 w.	
R1		19B800607P103		
			Metal film: 4.7K ohms ±5%, 1/8 w.	
R1		19B800607P272	Metal film: 2.7K ohms ±5%, 1/8 w.	
R1		19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R1		19B800607P1	Metal film: Jumper.	
R1		19A702931P369	Metal film: 51.1K ohms ±1%, 200 VDCW, 1/8 w.	
R1	8	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R1	9	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.	
R2	20	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R2	21	19B800607P223	Metal film: 22K ohms ±5%, 1/8 w.	
R2	22	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.	
R2	23	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R2	24	19B800607P122	Metal film: 1.2K ohms ±5%, 1/8 w.	
R2	25	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R2	26	19A702931P384	Metal film: 73.2K ohms ±1%, 200 VDCW, 1/8 w.	
R2	27	19A702931P388	Metal film: 80.6K ohms ±1%, 200 VDCW, 1/8 w.	
R2	28	19A702931P358	Metal film: 39.2K ohms ±1%, 200 VDCW, 1/8 w.	
R2		19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.	
R3		19A702931P384	Metal film: 73.2K ohms ±1%, 200 VDCW, 1/8 w.	
R3		19B800607P103	Metal film: 10K ohms $\pm 5\%$, 1/8 w.	
R3		19A702931P369	Metal film: 51.1K ohms \pm 1%, 200 VDCW, 1/8 w.	
R3		19A702931P325	Metal film: 17.8K ohms ±1%, 200 VDCW, 1/8 w.	
R3		19A702931P350	Metal film: 32.4K ohms ±1%, 200 VDCW, 1/8 w.	
R3		19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.	
R3		19A702931P382	Metal film: 69.8K ohms ±1%, 200 VDCW, 1/8 w.	
R3		19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.	
R3	9	19A702931P401	Metal film: 100K ohms \pm 1%, 200 VDCW, 1/8 w.	
R4	0	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R4	1	19B800607P104	Metal film: 100K ohms ±5%, 1/8 w.	
R4	2	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R4	3	19B800607P684	Metal film: 680K ohms ±5%, 1/8 w.	
R4	4	19B800607P473	Metal film: 47K ohms ±5%, 1/8 w.	
R4	5	19B800607P683	Metal film: 68K ohms $\pm 5\%$, 1/8 w.	
R4	6	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R4		19B800607P681	Metal film: 680 ohms \pm 5%, 1/8 w.	
and	d			
R4				
R4		19A702931P301	Metal film: 10K ohms \pm 1%, 200 VDCW, 1/8 w.	
R5	0	19A702931P388	Metal film: 80.6K ohms \pm 1%, 200 VDCW, 1/8 w.	
R5		19B800607P472	Metal film: 4.7K ohms ±5%, 1/8 w.	
thr				
	3	-		
R5		19B800607D102	Metal film: 10K ohms +5% 1/9 w	
R5 R5	64	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	
R5	i4 i5	19B800607P103 19B800607P472	Metal film: 10K ohms $\pm 5\%$, 1/8 w. Metal film: 4.7K ohms $\pm 5\%$, 1/8 w.	

*COMPONENTS, ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

PARTS LIST

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LBI-38764
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SYMBOL	PART NO.	DESCRIPTION
R57	19B800607P1	Metal film: Jumper.
and	10200000111	
R58		
R59	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.
R60	19B800607P471	Metal film: 470 ohms ±5%, 1/8 w.
R61	19A702931P413	Metal film: 133K ohms ±1%, 200 VDCW, 1/8 w.
R62 R63	19A702931P327 19B800607P103	Metal film: 18.7K ohms ±1%, 200 VDCW, 1/8 w. Metal film: 10K ohms ±5%, 1/8 w.
R64	19A702931P177	Metal film: for onins $\pm 3\%$, 1/8 w. Metal film: 619 ohms $\pm 1\%$, 200 VDCW, 1/8 w.
R65	19B800607P682	Metal film: 6.8K ohms \pm 5%, 1/8 w.
R66	19A702931P243	Metal film: 2740 ohms ±1%, 200 VDCW, 1/8 w.
R67	19B800607P103	Metal film: 10K ohms \pm 5%, 1/8 w.
R68	19B800607P153	Metal film: 15K ohms ±5%, 1/8 w.
R69	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.
R70	19B800607P104	Metal film: 100K ohms ±5%, 1/8 w.
R71	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.
R72	19A702931P269	Metal film: 5110 ohms ±1%, 200 VDCW, 1/8 w.
R73	19A702931P313	Metal film: 13.3K ohms ±1%, 200 VDCW, 1/8 w.
R74	19B800607P561	Metal film: 560 ohms ±5%, 1/8 w.
R75 and	19B800607P224	Metal film: 220K ohms \pm 5%, 1/8 w.
R76		
R77	19A702931P376	Metal film: 60.4K ohms \pm 1%, 200 VDCW, 1/8 w.
R78	19A702931P222	Metal film: 1650 ohms \pm 1%, 200 VDCW, 1/8 w.
R80 and	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.
R81		
R82	19B800607P562	Metal film: 5.6K ohms ±5%, 1/8 w.
R83	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.
R84	19B800607P823	Metal film: 82K ohms ±5%, 1/8 w.
R85	19A702931P434	Metal film: 221K ohms ±1%, 200 VDCW, 1/8 w.
R86	19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.
R87	19B800607P105	Metal film: 1M ohms \pm 5%, 1/8 w.
R88 R89	19A702931P305 19A702931P384	Metal film: 11K ohms \pm 1%, 200 VDCW, 1/8 w. Metal film: 73.2K ohms \pm 1%, 200 VDCW, 1/8 w.
R90	19A702931P358	Metal film: 73.2 K ohms $\pm 1\%$, 200 VDCW, 1/8 w. Metal film: 39.2 K ohms $\pm 1\%$, 200 VDCW, 1/8 w.
R91	19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.
R92	19A702931P384	Metal film: 73.2K ohms ±1%, 200 VDCW, 1/8 w.
R93	19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.
R94	19A702931P388	Metal film: 80.6K ohms ±1%, 200 VDCW, 1/8 w.
R95	19A702931P325	Metal film: 17.8K ohms ±1%, 200 VDCW, 1/8 w.
R96	19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.
R97	19A702931P382	Metal film: 69.8K ohms \pm 1%, 200 VDCW, 1/8 w.
R98	19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.
R99	19A702931P350	Metal film: 32.4K ohms ±1%, 200 VDCW, 1/8 w.
R100 R101	19B800607P471 19B800607P102	Metal film: 470 ohms ±5%, 1/8 w. Metal film: 1K ohms ±5%, 1/8 w.
R101	19B800607P102	Metal film: 1K onms \pm 5%, 1/8 w. Metal film: 56K ohms \pm 5%, 1/8 w.
R102	19B800607P123	Metal film: 12K ohms $\pm 5\%$, 1/8 w.
R104	19B800607P472	Metal film: 4.7K ohms $\pm 5\%$, 1/8 w.
and P105		· ·
R105 R106	19A702931P355	Metal film: 36.5K ohms ±1%, 200 VDCW, 1/8 w.
R100	19A702931P355	Metal film: 36.5K on $\pm 1\%$, 200 VDCW, 1/8 w. Metal film: 7500 ohms $\pm 1\%$, 200 VDCW, 1/8 w.
R107	19A702931P177	Metal film: $619 \text{ ohms } \pm 1\%$, 200 VDCW, 1/8 w.
R109	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.
R110	19B800607P105	Metal film: 1M ohms \pm 5%, 1/8 w.
R111	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.
R112	19A702931P401	Metal film: 100K ohms ±1%, 200 VDCW, 1/8 w.
and R113		
R114	19A702931P383	Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.
R115	19B800607P391	Metal film: 390 ohms $\pm 5\%$, 1/8 w.
and R116		
R116 R117	19A702931P385	Metal film: 75K ohms ±1%, 200 VDCW, 1/8 w.
		1/0, 200 VDOVV, 1/0 W.

PA	RTS	LIST

SYMBOL	PART NO.	DESCRIPTION	SYMBOL
R120	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	R185
R121	19A702931P342	Metal film: 26.7K ohms ±1%, 200 VDCW, 1/8 w.	R186
R122	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.	
R124	19A702931P325	Metal film: 17.8K ohms $\pm 1\%$, 200 VDCW, 1/8 w.	
R125	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	SW2 thru
R126	19B800607P472	Metal film: 4.7K ohms ±5%, 1/8 w.	SW4
R127	19A702931P401	Metal film: 100K ohms \pm 1%, 200 VDCW, 1/8 w.	
R128 and	19A702931P222	Metal film: 1650 ohms ±1%, 200 VDCW, 1/8 w.	U1
R129			
R130	19A702931P422	Metal film: 165K ohms ±1%, 200 VDCW, 1/8 w.	U2
R132	19B800607P332	Metal film: 3.3K ohms ±5%, 1/8 w.	U3
R133	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	U4
and R134			U5
R135	19A702931P313	Metal film: 13.3K ohms ±1%, 200 VDCW, 1/8 w.	
R136	19B800607P103	Metal film: 10K ohms $\pm 5\%$, 1/8 w.	U6
and			117
R137			U7
R138	19A702931P285	Metal film: 7500 ohms ±1%, 200 VDCW, 1/8 w.	U8
R139	19A702931P389	Metal film: 82.5K ohms ±1%, 200 VDCW, 1/8 w.	
R140	19B800607P224	Metal film: 220K ohms ±5%, 1/8 w.	U9
R141	19A702931P269	Metal film: 5110 ohms ±1%, 200 VDCW, 1/8 w.	U10
R142	19B800607P474	Metal film: 470K ohms ±5%, 1/8 w.	U11
R143	19A702931P436	Metal film: 232K ohms ±1%, 200 VDCW, 1/8 w.	U12
R144 R145	19A702931P243 19B800607P224	Metal film: 2740 ohms ±1%, 200 VDCW, 1/8 w.	U13
R145 R146	19B800607P224	Metal film: 220K ohms ±5%, 1/8 w. Metal film: 470K ohms ±5%, 1/8 w.	U14
R140 R147	19B800607P474	Metal film: 470 K on 55% , $1/8$ w. Metal film: 10 K ohms $\pm 5\%$, $1/8$ w.	_
R148	19B800607P153	Metal film: 15K ohms \pm 5%, 1/8 w.	U15
R149	19B800607P103	Metal film: 10K ohms $\pm 5\%$, 1/8 w.	U16 and
thru			U17
R151			U18
R152	19B800607P102	Metal film: 1K ohms \pm 5%, 1/8 w.	
R153 R155	19B800607P103 19A702931P434	Metal film: 10K ohms ±5%, 1/8 w.	U19
R155 R156	19A702931P434 19A702931P406	Metal film: 221K ohms ±1%, 200 VDCW, 1/8 w.	U20
R156 R157	19B800607P472	Metal film: 113K ohms ±1%, 200 VDCW, 1/8 w. Metal film: 4.7K ohms ±5%, 1/8 w.	U21
R158	19A702931P383	Metal film: 71.5K ohms \pm 1%, 200 VDCW, 1/8 w.	
R159	19B800607P472	Metal film: 4.7K ohms ±5%, 1/8 w.	U22
R160	19A702931P177	Metal film: 619 ohms ±1%, 200 VDCW, 1/8 w.	U24
R161	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.	U25
R162	19B800607P474	Metal film: 470K ohms ±5%, 1/8 w.	020
R163	19B800607P102	Metal film: 1K ohms $\pm 5\%$, 1/8 w.	U26
R164	19B800607P472	Metal film: 4.7K ohms ±5%, 1/8 w.	U27
R165	19B800607P682	Metal film: 6.8K ohms ±5%, 1/8 w.	U28
R166	19A702931P355	Metal film: 36.5K ohms ±1%, 200 VDCW, 1/8 w.	U29
R167	19A702931P325	Metal film: 17.8K ohms ±1%, 200 VDCW, 1/8 w.	025
R168	19A702931P305	Metal film: 11K ohms ±1%, 200 VDCW, 1/8 w.	U30
R169	19A702931P393	Metal film: 90.9K ohms $\pm 1\%,$ 200 VDCW, 1/8 w.	U31
R170	19B800607P472	Metal film: 4.7K ohms ±5%, 1/8 w.	U32
and R171			and U33
R172	19B800607P474	Metal film: 470K ohms ±5%, 1/8 w.	U34
and			
R173 R174	19A702931P313	Matal films 40.01/ along 140/ 200 \/DO\\/ 4/0.00	U35 and
	19B800607P333	Metal film: 13.3K ohms ±1%, 200 VDCW, 1/8 w.	U36
R175 R176	19A702931P222	Metal film: 33K ohms ±5%, 1/8 w. Metal film: 1650 ohms ±1%, 200 VDCW, 1/8 w.	U37
R170 R177	19A702931P222	Metal film: 1050 onms $\pm 1\%$, 200 VDCW, 1/8 w. Metal film: 5110 ohms $\pm 1\%$, 200 VDCW, 1/8 w.	U40
R178	19B800607P474	Metal film: 470K ohms $\pm 5\%$, 1/8 w.	U41
R179	19A702931P385	Metal film: 75K ohms ±1%, 200 VDCW, 1/8 w.	VIII
R180	19A702931P413	Metal film: 133K ohms ±1%, 200 VDCW, 1/8 w.	XU4
R181	19A702931P130	Metal film: 200 ohms ±1%, 200 VDCW, 1/8 w.	
R183	19B800607P183	Metal film: 18K ohms \pm 5%, 1/8 w.	Y1
R184	19B800607P104	Metal film: 100K ohms ±5%, 1/8 w.	

YMBOL	PART NO.	DESCRIPTION
R185	19B800607P473	Metal film: 47K ohms ±5%, 1/8 w.
	19B800607P473	-
R186	1300000/14/2	Metal film: 4.7K ohms ±5%, 1/8 w.
		SWITCHES
SW2	19A705959P3	Switch, toggle: SPDT, 0.4 A @ 20 volts; sim to C
thru	19A703939F3	& K T101-M-H9-A-B-E.
SW4		
		INTEGRATED CIRCUITS
U1	19A705982P101	Microcomputer: 8-bit extended I/O; sim to INTEL
		80C152JB-1.
U2	19A703471P302	Digital: Octal Data Latch; sim to 74HC373.
U3	19A703471P320	Digital: 3-Line To 8-Line Decoder; sim to
U4	344A3307G13	74HC138. EPROM Kit.
U4 U5	19A705603P5	Digital: 8K x 8-Bit Static CMOS RAM; sim to
00	13710300353	KM6264AL-10
U6	19A703952P102	EEPROM: 2K X 8, 5 Volts, programmable; sim to
		XICOR X2816CP-20.
U7	19A704380P319	Digital: CMOS Octal Data Flip-Flop; sim to
110	10470070505	74HC377.
U8	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer; sim to 4053BM.
U9	344A3070P3	Digital: JFET, Input guad Op Amp; sim to TL074.
U10	19A704883P2	Digital: Quad Op Amp; sim to MC3303D.
U11	19A116297P7	Linear: Dual Op Amp; sim to MC4558CD.
U12	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer; sim
J		to 4053BM.
U13	19A704883P2	Digital: Quad Op Amp; sim to MC3303D.
U14	19A702705P3	Digital: 8-Channel Analog Multiplexer; sim to
		4051BM.
U15	344A3856P101	CMOS Analog Multiplexer; sim to DG408D.
U16 and	19A704883P2	Digital: Quad Op Amp; sim to MC3303D.
U17		
U18	19A704380P302	Digital: CMOS Dual Data Flip-Flop; sim to
		74HC74.
U19	19A149895P1	Digital: supervisory circuit; sim to MAXIM
1100	1041161000575	MAX691C.
U20	19A116180P575	Digital: Hex Open Collector Inverter: sim to 7406.
U21	19A703995P3	Digital: High speed logic, hex inverter, unbuffered; sim to 74HCU04.
U22	344A3039P201	Digital: Driver/receiver, EIA-232D/V.28; sim to
		MČ145406.
U24	19A705980P101	Tranxceiver, differential Bus; sim to SN751768.
U25	19A703471P316	Digital: Driver/receiver, octal 3-state non inverting
1106	1041161000575	buffer; sim to 74HC541.
U26	19A116180P575	Digital: Hex Open Collector Inverter: sim to 7406.
U27	19A705979P101	Digital: CMOS A/D; sim to TL549CP.
U28	19A704380P302	Digital: CMOS Dual Data Flip-Flop; sim to 74HC74.
U29	19A149466P301	Digital: CH MOS, programmable timer; sim to IN-
		TEL 82C54.
U30	19A704883P2	Digital: Quad Op Amp; sim to MC3303D.
U31	344A3070P3	Digital: JFET, Input quad Op Amp; sim to TL074.
U32	19A702705P3	Digital: 8-Channel Analog Multiplexer; sim to
and U33		4051BM.
U33 U34	19A705991P101	Digital: Programmable interface: sim to Harris
034	19A105991P101	Digital: Programmable interface; sim to Harris C82C55A.
U35	344A3041P201	Digital: dual in-line potentiometers, ceramic, her-
and		metically sealed; sim to DS1267S-10.
U36		
U37	19A704883P2	Digital: Quad Op Amp; sim to MC3303D.
U40	19A116180P575	Digital: Hex Open Collector Inverter: sim to 7406.
U41	19A700176P101	Digital: Hex Inverting Buffer/Converter; sim to 4049UBD.
XU4	19A705840P2	40490BD. Socket: sim to Amp 643646-3.
704	1 JAI 00040FZ	
		CRYSTALS
Y1	19A702511G37	Crystal Assembly: 14.7456 MHz.
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SYMBOL	PART NO.	DESCRIPTION	SYMBOL	PART NO.	DESCRIPTION
		DIGITAL SIGNAL PROCESSOR	R34	19A702931P331	Metal film: 20.5K ohms ±1%, 200 VDCW, 1/8 w.
		19D902667G1	R35	19A702931P201	Metal film: 1000 ohms \pm 1%, 200 VDCW, 1/8 w.
			R36	19A702931P317	Metal film: 14.7K ohms ±1%, 200 VDCW, 1/8 w.
		CAPACITORS	R37	19A702931P331	Metal film: 20.5K ohms $\pm 1\%$, 200 VDCW, 1/8 w.
C1	19A702052P26	Ceramic: 0.1 $\mu\text{F}\pm$ 10%, 50 VDCW.	R38	19A702931P377	Metal film: 61.9K ohms ±1%, 200 VDCW, 1/8 w.
thru C15			R39	19A702931P307	Metal film: 11.5K ohms \pm 1%, 200 VDCW, 1/8 w.
C16	19A702061P29	Ceramic: 22 pF \pm 5%, 50 VDCW, temp coef 0 \pm 30	R40	19A702931P347	Metal film: 30.1K ohms ±1%, 200 VDCW, 1/8 w.
and	10/11 020011 20		R41	19A702931P157	Metal film: 383 ohms $\pm 1\%$, 200 VDCW, 1/8 w.
C17			and	10, 11 020011 101	Netarinini. 000 0mm3 ±170, 200 V DOW, 170 W.
C18 thru	19A705205P6	Tantalum: 10 μF, 16 VDCW; sim to Sprague 293D.	R42		
C22			R43	19A702931P339	
C24	19A702052P107	Ceramic: 2200 pF ± 5%, 50 VDCW.	R44	19A702931P347	Metal film: 30.1K ohms ±1%, 200 VDCW, 1/8 w.
C25	19A702061P53	Ceramic: 68 pF \pm 5%, 50 VDCW, temp coef 0 \pm 30	R45	19A702931P307	Metal film: 11.5K ohms ±1%, 200 VDCW, 1/8 w.
		PPM.	R46	19A702931P294	Metal film: 9310 ohms ±1%, 200 VDCW, 1/8 w.
C26	19A702052P120	Ceramic: 0.033 $\mu\text{F}\pm$ 5%, 50 VDCW.	R47	19A702931P265	
C27	19A705205P19	Tantalum: 2.2 µF ±20%, 10VDCW; sim to	R48	19A702931P294	Metal film: 9310 ohms ±1%, 200 VDCW, 1/8 w.
and C28		Sprague 293D.	R49	19A702931P201	Metal film: 1000 ohms $\pm 1\%$, 200 VDCW, 1/8 w.
C20 C29	19A702052P134	Ceramic: 0.1uF ± 5%. 25	thru R51		
C30	19A702052P112	Ceramic: $6800 \text{ pF} \pm 5\%$, 50 VDCW.	R55	19A702931P301	Metal film: 10K ohms ±1%, 200 VDCW, 1/8 w.
C30 C31	19A702052P112	Ceramic: $1000 \text{ pF} \pm 5\%$, 50 VDCW .	R56	19A702931P339	Metal film: 24.9K ohms $\pm 1\%$, 200 VDCW, 1/8 w.
C32	19A702052P105	Ceramic: 1000 pF \pm 5%, 50 VDCW. Ceramic: 0.082 μ F \pm 5%, 16 VDCW.	R57	19A702931P301	Metal film: 10K ohms $\pm 1\%$, 200 VDCW, 1/8 w.
C32 C33	19A702052P142	Ceramic: $0.082 \mu\text{F} \pm 5\%$, 16 VDCW. Ceramic: $6800 \text{pF} \pm 5\%$, 50 VDCW.			
and	19A702032F112	Ceramic: 6800 pF ± 5%, 50 VDCW.			INTEGRATED CIRCUITS
C34 C35	19A702052P105	Ceramic: 1000 pF ± 5%, 50 VDCW.	U1	344A3038P101	Digital: DSP microcomputer, oper freq. 40.96 MHz; sim to ADSP210KX-40.
C38	19A7020521 105	Ceramic: 47 pF \pm 5%, 50 VDCW, temp coef 0 + or -	U4	19A705827P1	Encoder/Decoder: sim to Texas Instruments
0.00	1941020011 43	30 PPM.	and U5	19410302111	TCM29C23.
		DIODES	U6	344A3309G5	EPROM Kit.
D1 and	19A700053P2	Silicon: 2 Diodes in Series; sim to BAV99.	U7	344A3064P203	Digital: HI-SPEED, octal D type FF, pos. edge trig.; sim to 74HCT377.
D2			U8	344A3064P201	Digital: HI-SPEED, 3-8 line decoder/demultiplexer, inverting; sim to 74HCT138.
Do	404704770044	PLUGS	U9	344A3064P204	Digital: HI-SPEED, octal buffer/line driver, 3-state; sim to 74HCT541
P2 and P3	19A704779P14	Connector, 15 pin.	U10	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer; sim to 4053BM.
		RESISTORS	U11	19A704883P2	Digital: Quad Op Amp; sim to MC3303D.
R2	19B800607P1		U12	344A3040P201	Digital: SRAM, 1K X 8 Dual port; sim to
R2 R4	19B800607P1 19B800607P1	Metal film: Jumper.	1140	044400040000	IDT7130SA100.
	19B800607P1 19B800607P683	Metal film: Jumper.	U13	344A3064P202	Digital: HI-SPEED, transparent ltch, 3-state; sim to 74HCT373.
R5 and R6	190000072003	Metal film: 68K ohms ±5%, 1/8 w.	U15	344A3041P201	Digital: dual in-line potentiometers, ceramic, hermeti- cally sealed; sim to DS1267S-10.
R7	19B800607P1	Metal film: Jumper.	U16	344A3070P3	Digital: JFET, Input guad Op Amp; sim to TL074.
R10	19B800607P682	Metal film: 6.8K ohms ±5%, 1/8 w.	U17	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer; sim to 4053BM.
R12 and	19B800607P1	Metal film: Jumper.	U18	344A3070P3	Digital: JFET, Input quad Op Amp; sim to TL074.
R13 R14	19A702931P355				
and	19A702931F333	Metal film: 36.5K ohms \pm 1%, 200 VDCW, 1/8			SOCKETS
R15			X1	19A702511G30	Crystal, quartz: 8.192 MHz.
R16	19A702931P318	Metal film: 15K ohms \pm 1%, 200 VDCW, 1/8 w.			
R17	19A702931P401	Metal film: 100K ohms \pm 1%, 200 VDCW, 1/8 w.		1000050000	SOCKETS
R18	19B800607P201	Metal film: 200 ohms ±5%, 1/8 w.	XU1	19B235688P1	Socket,PLCC
R20	19B800607P392	Metal film: 3.9K ohms ±5%, 1/8 w.	XU6	19A705840P2	Socket: sim to Amp 643646-3.
R21	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.			
R23	19B800607P103	Metal film: 10K ohms ±5%, 1/8 w.			
thru R27					
R28 and R29	19B800607P102	Metal film: 1K ohms ±5%, 1/8 w.			
R29 R30	19A702931P418	Metal film: 150K ohms ±1%, 200 VDCW, 1/8 w.			
R30 R31	19A702931P418	Metal film: 150K onms \pm 1%, 200 VDCW, 1/8 w.			
1.01		Metal film: 15K onms \pm 1%, 200 VDCW, 1/8 w. Metal film: 1210 ohms \pm 1%, 200 VDCW, 1/8 w.			
B33					
R32 R33	19A702931P209 19A702931P369	Metal film: 51.1K ohms ±1%, 200 VDCW, 1/8 w.			

PRODUCTION CHANGES

Changes to the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by those revisions.

System Module - 19D902590G2

To standardize production of MASTR IIe and MASTR III System Modules, changed MASTR IIe System Board from 19D902453G1 to 19D902771G1.

MASTR IIe System Board was: 19D902453G1 (see LBI-38639 for a description of this board).

System Board - 19D902771G1

Rev. A: To improve operation, changed R57 from 19B800607P472 (4.7K ohms) to 19A702931P305 (11k ohms).

- To make MASTR IIe and MASTR III System Boards compatible, Rev. B: changed R127 from 19A702931P269 (5.11K ohms) to 19A702931P401 (100K ohms).
- To enhance audio routing by supplying CAS in the System Rev. C: Module in auxiliary receiver applications. Changed the following resistors:

Changed R24 from 19B800607P822 (8.2K ohms) to 19B800607P272 (2.7K ohms).

Changed R57 from 19B702931P305 (11K ohms) to 19B8800607P1 (Jumper).

Changed R82 from 19B800607P103 (19K ohms) to 19B800607P562 (5.6K ohms).

- To improve performance, changed R24 from 19B800607P272 (2.7K ohms) to 19B800607P122 (1.2K ohms). Rev. D:
- In order to meet the 10% variance of the complete audio path. Rev. E: Changed the following capacitors: Changed C79 from 19A702052P14 (±10%) to 19A702052P114 (±5%). Changed C103 from 19A702052P14 (±10%) to 19A702052P114 (±5%).

Digital Signal Processor - 19D902667G1

Incorporated into initial shipment. Rev. A-C:

To invert SYSBD Line in to accommodate 2-wire line audio Rev. D: cancellation, added C36-C38, D2, R50-R54, R56, R57, and U18. Changed C29 and deleted R155.

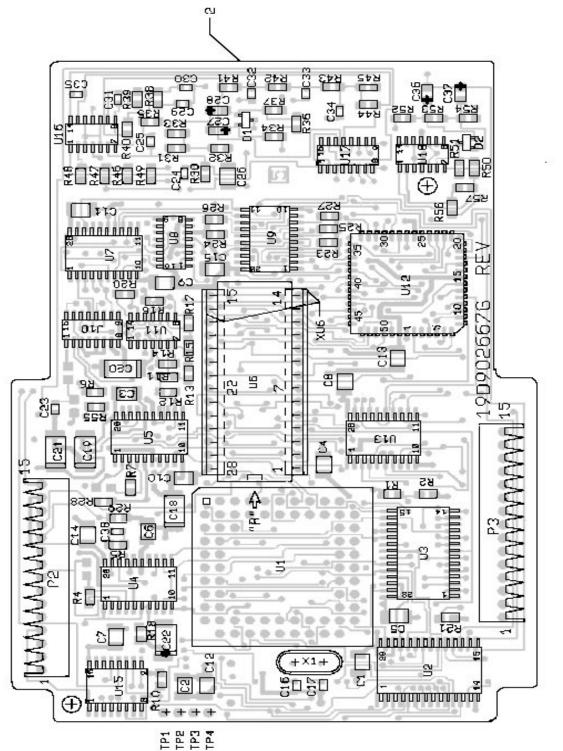
C29 was: 19A702052P26, 0.1 µF 10%, 50 VDCW.

Rev. E: To adjust analog signal levels to protect hardware from excessive signal levels, changed R50, R51, and R53 and Deleted U2 and U3.

> Changed R50 from 19A702931P265 (4640 ohms) to 19A702931P201 (1.0K ohms).

Changed R51 from 19A702931P265 (4640 ohms) to 19A702931P201 (1.0K ohms).

Changed R53 from 19A702931P305 (11K ohms) to 19A702931P265 (4640 ohms).



COMPONENT SIDE

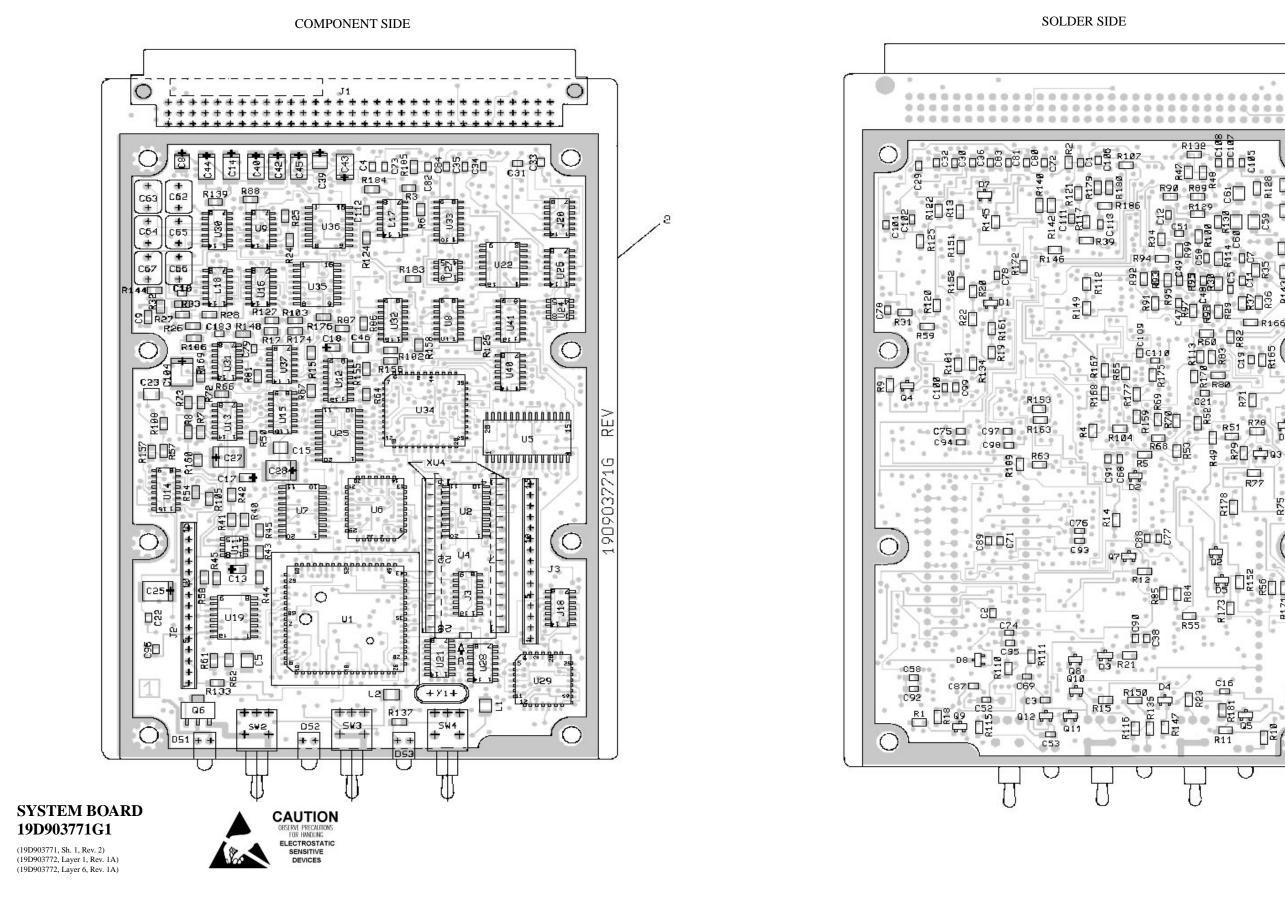
LBI-38764

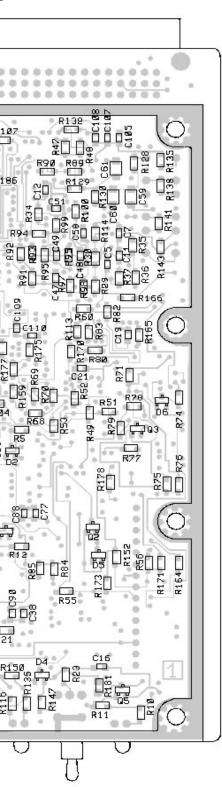


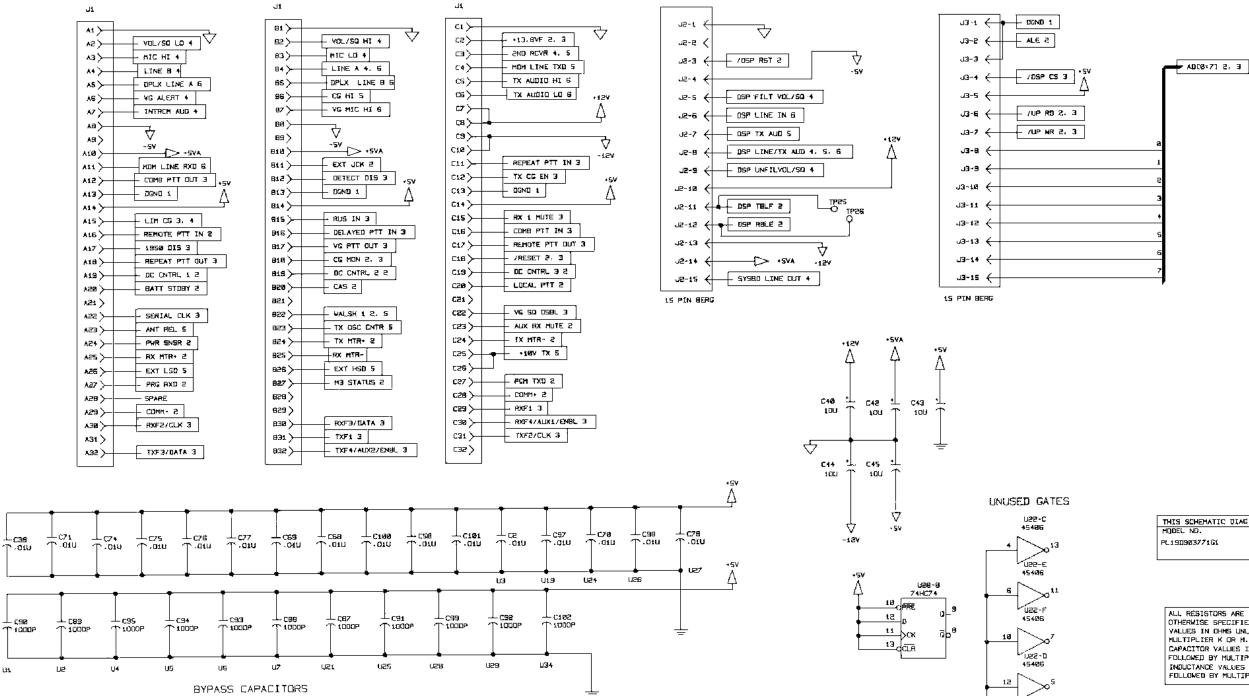


(19D902667, Sh. 1, Rev. 5) (19D902668, Layer 1, Rev. 5)

OUTLINE DIAGRAM







un.

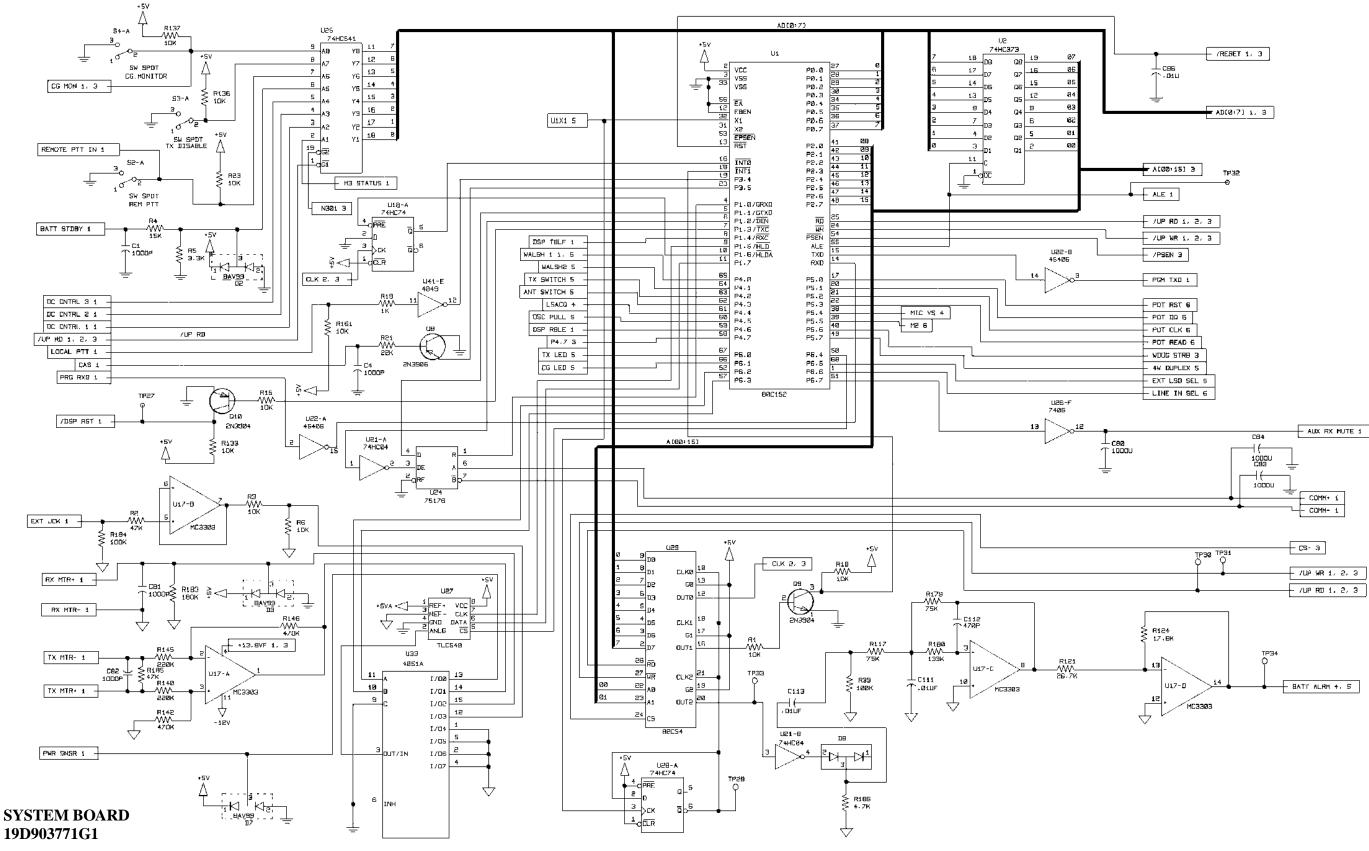
LBI-38764

THIS SCHEMATIC DIAG APPLIES TO REV LETTER E

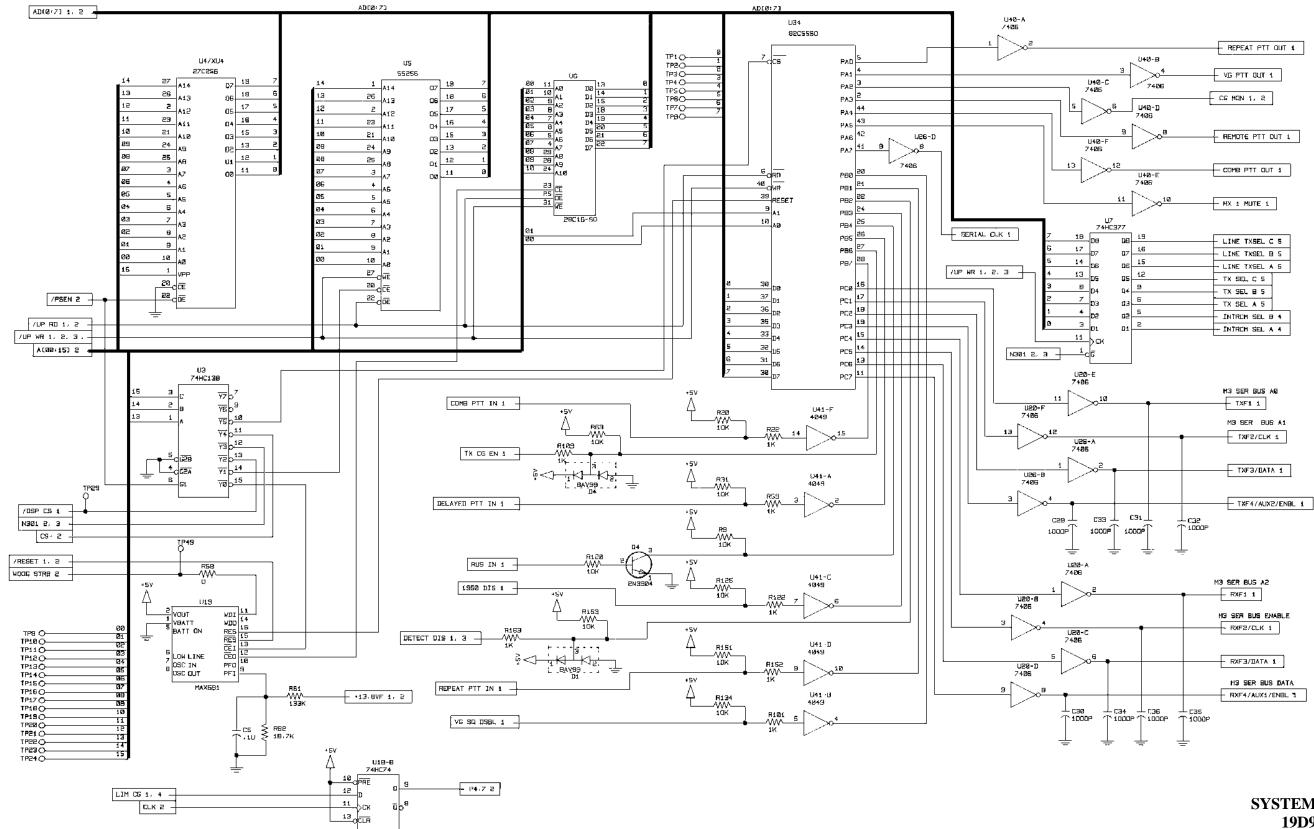
ALL RESISTORS ARE 0.1 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN DHMS UNLESS FOLLOWED BY MULTIPLIER K OR M. CAPACITOR VALUES IN F UNLESS FOLLOWED BY MULTIPLIER U. N OR P INDUCTANCE VALUES IN # UNLESS FOLLOWED BY MULTIPLIER M OR (

SYSTEM BOARD 19D903771G1

(19D903770, Sh. 1, Rev. 7)



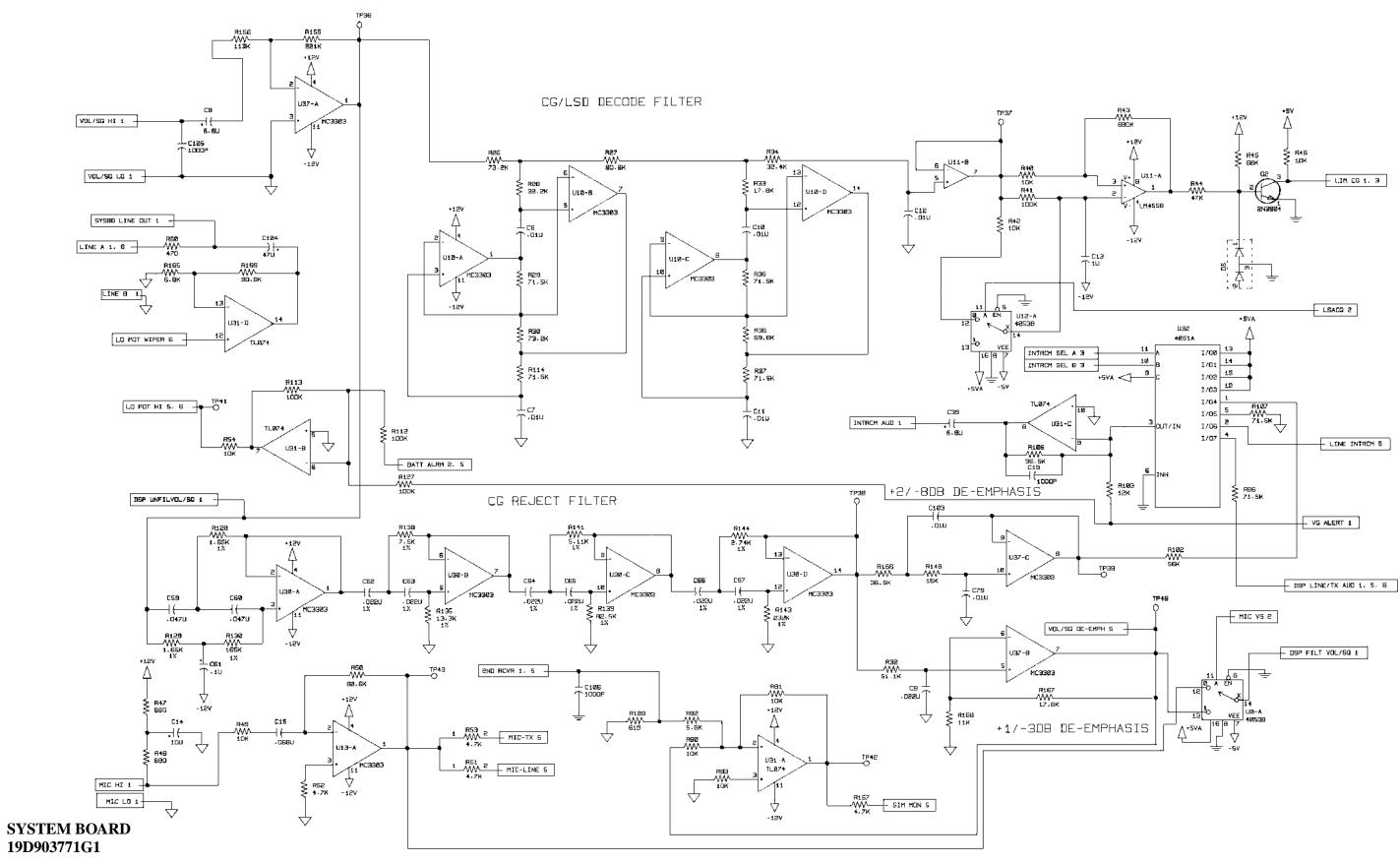
(19D903770, Sh. 2, Rev. 2)



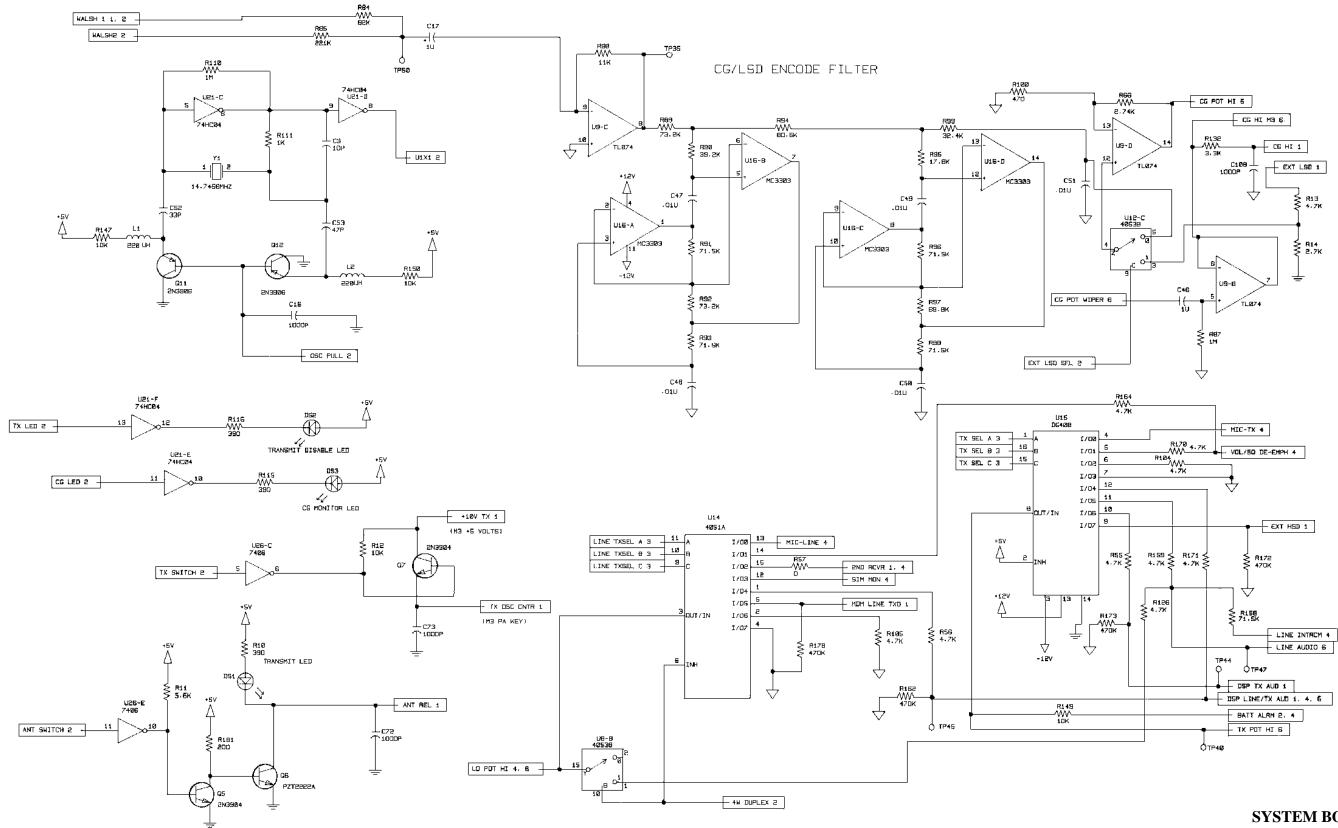
LBI-38764

SYSTEM BOARD 19D903771G1

(19D903770, Sh. 3, Rev. 1)



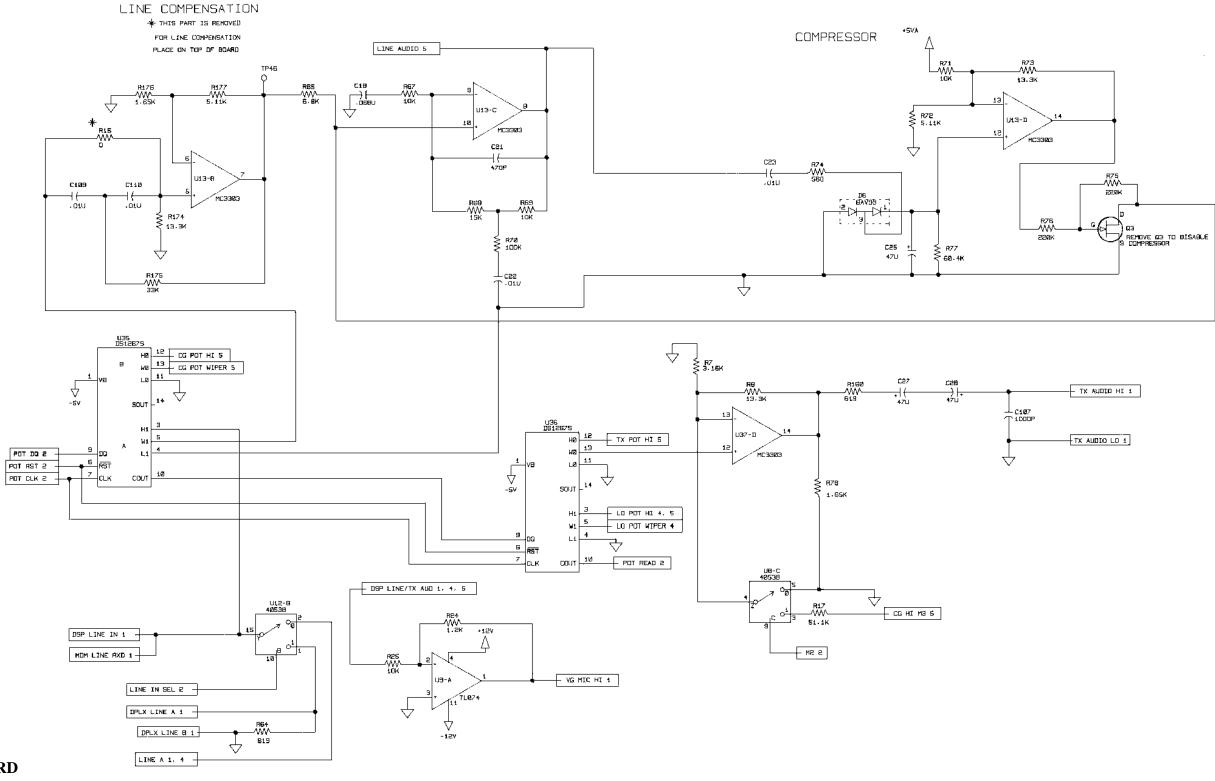
(19D903770, Sh. 4, Rev. 3)



LBI-38764

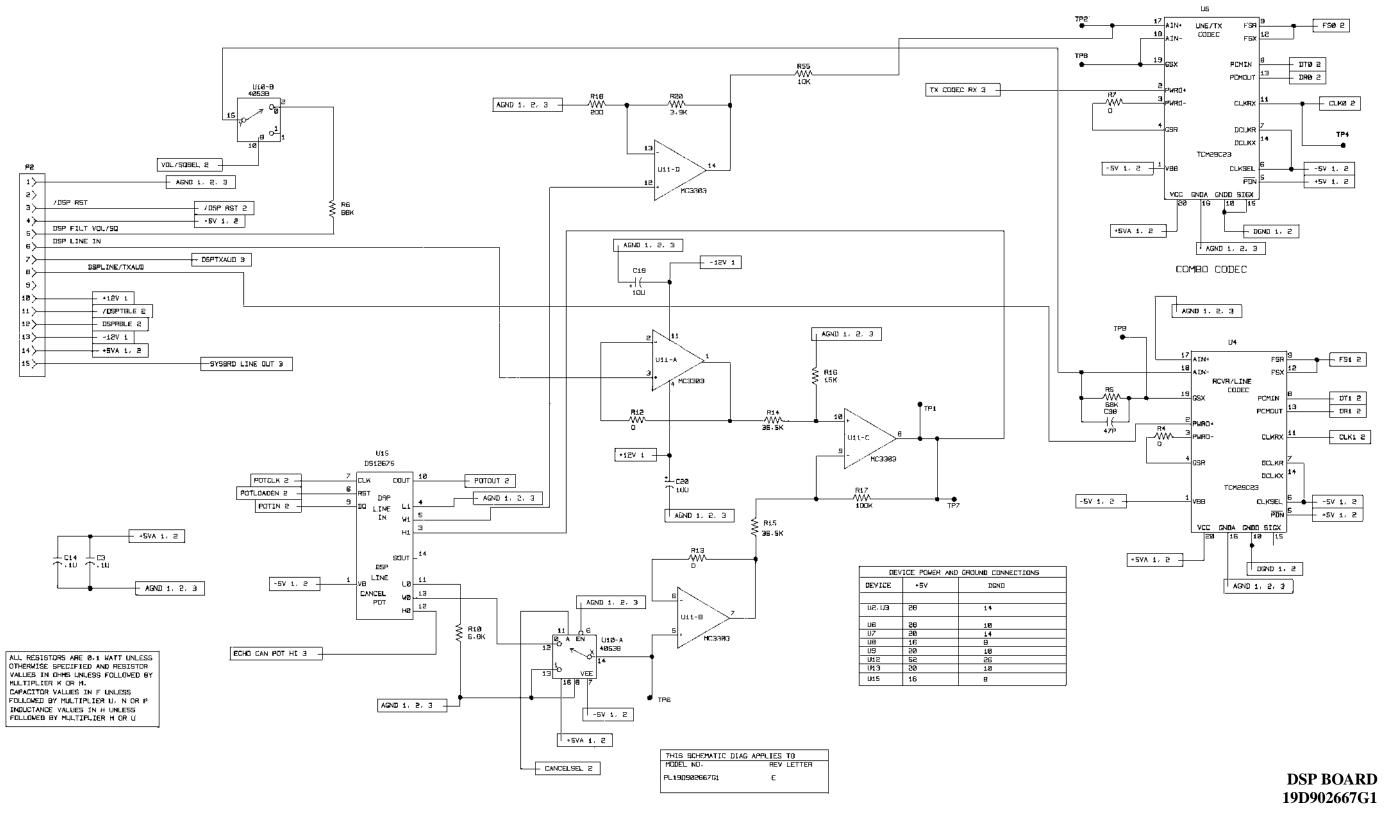
SYSTEM BOARD 19D903771G1

(19D903770, Sh. 5, Rev. 3)

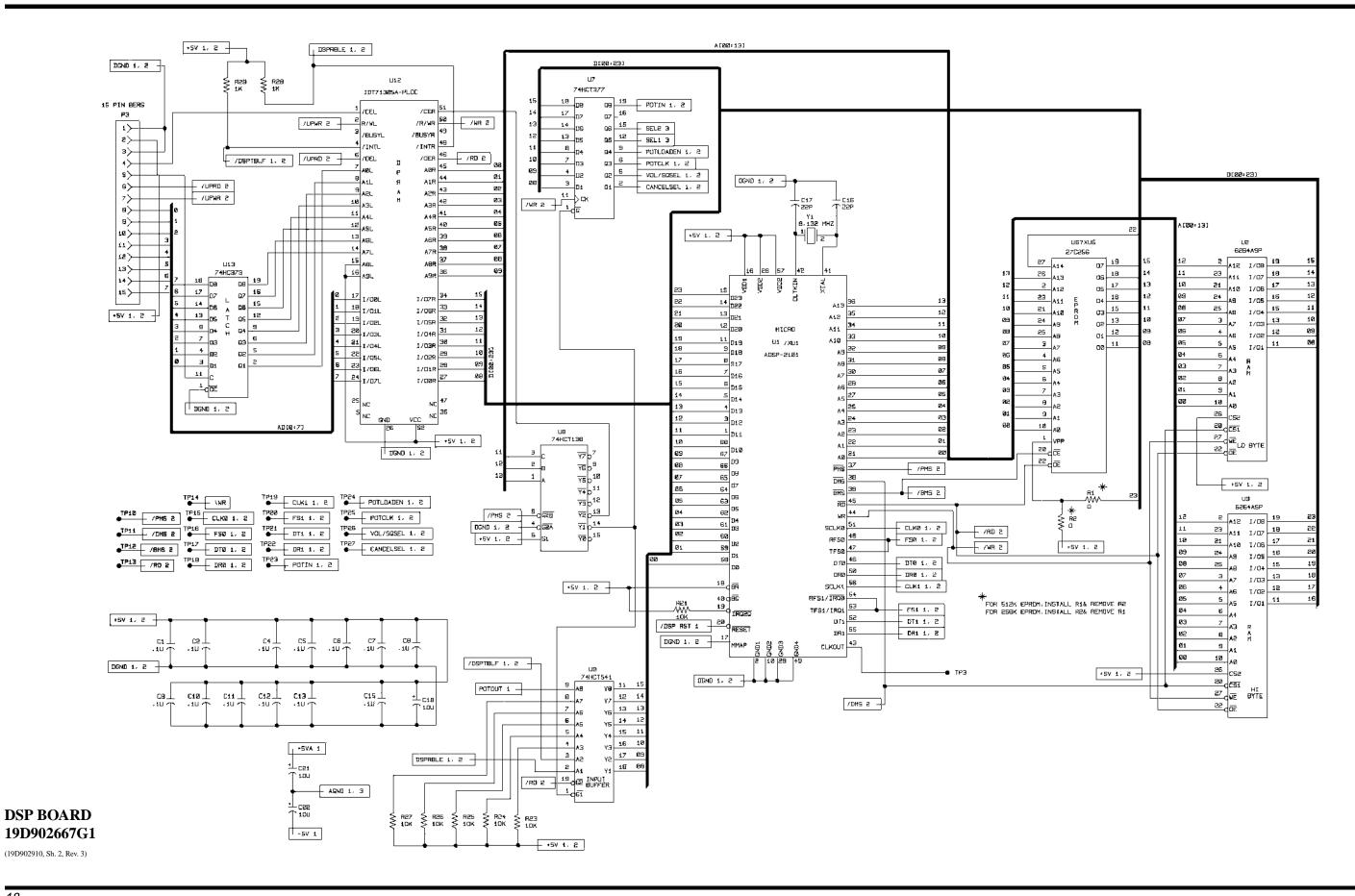


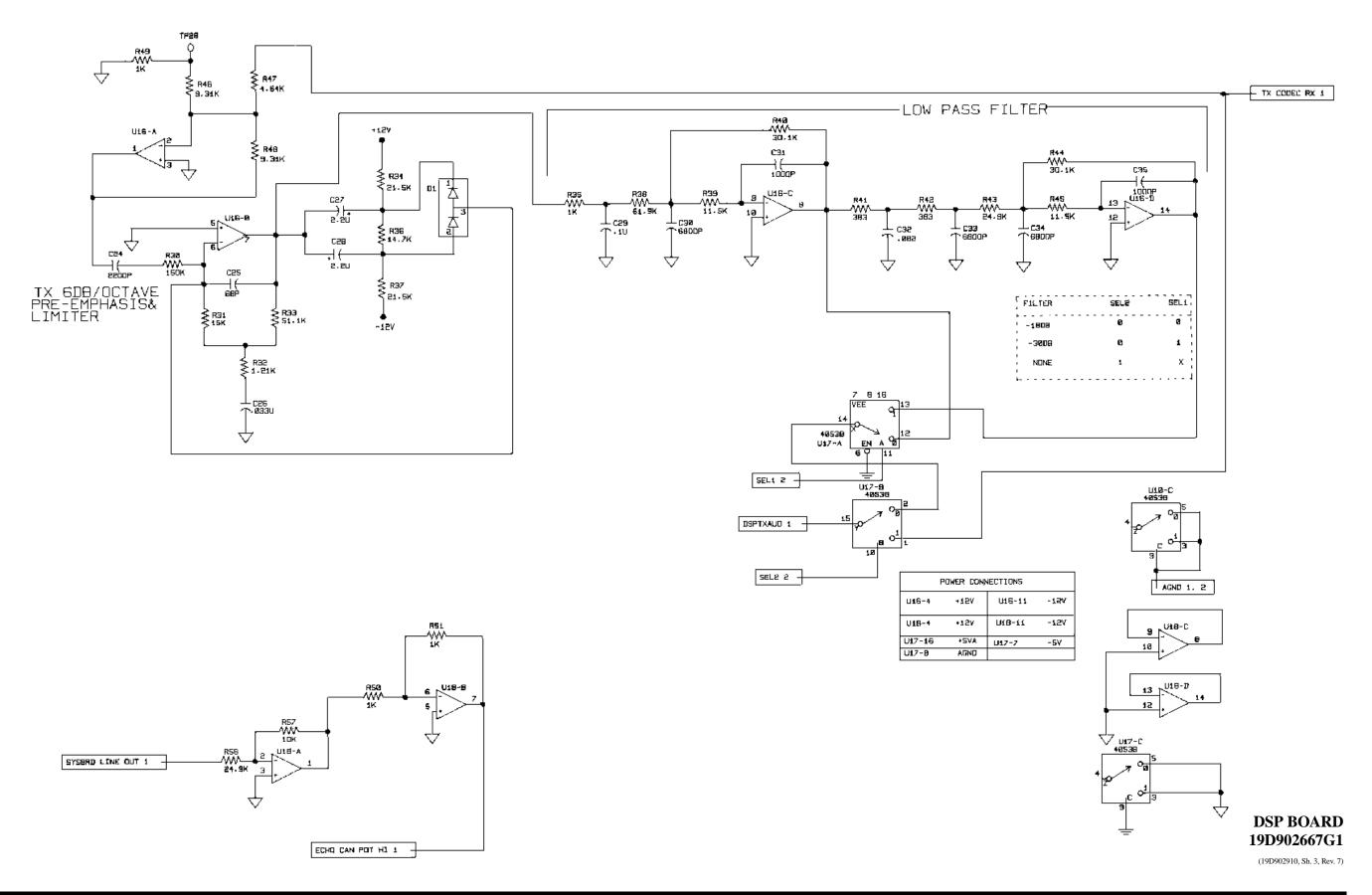
SYSTEM BOARD 19D903771G1

(19D903770, Sh. 6, Rev. 3)



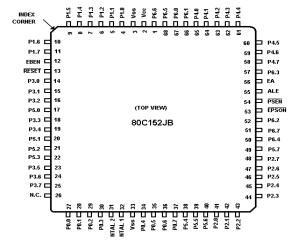
(19D902910, Sh. 1, Rev. 9)





LBI-38764

U1, Microcomputer 19A705982P101



Output

A <u>(1)</u>)

c (3)

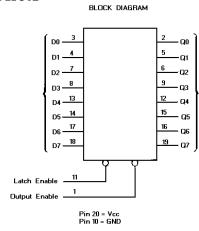
G1 (6)

GZA (4)

G2B (5)

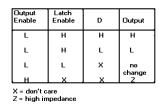
в

U2, Octal Data Latch 19A703471P302



PIN ASSIGNMENT				
Enable [20	Vec	
Q0 C	2	19] Q7	
DO D	3	18	D7	
D1 🛙	4	17	De	
Q1 🛙	5	16] Q6	
Q2 [6	15] Q5	
D2 🛙	7	14	D5	
D3 🛙	8	13	D4	
Q3 🛙	9	12	Q4	
GND 🛛	10	11	Latch Enable	

FUNCTION TABLE



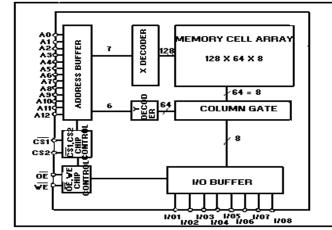
U3, 19A703471P120 3-to-8 Decoder/Demultiplexer

A [] 1 (J16 Vcc
в 🗖 2	15 YO
с 🛛 З	14 🛛 Y1
GZA∐4	13🛛 Y2
GZB∏5	12 🛛 Y3
G1 🗖 6	11🗋 Y4
Y7[]7	10 🛛 Y5
GND∐8	9🛛 Y6

SYSTEM MODULE

U4, EPROM Kit					
344A33	507G	5			
A15 🗌	1 C	, ²⁸] Vcc		
A12	2	27	_ A14		
A7 🗌	3	26	_ A13		
A6 🗌	4	25	_ A8		
A5	5	24	_ A9		
A4 🗌	6	23	_ A11		
A3	7	22	G/∨p		
A2	8	21	_ A10		
A1	9	20]E		
A0 🗌	10	19	_ Q8		
ଭୀ 🗌	11	18	_Q7		
ର୍2 🗌	12	17	_Q6		
Q3 🗌	13	16	_Q5		
GND 🗌	14	15	_ Q4		

PIN ARRAN	IGEMENT
NC 1 A12 2 A7 3 A6 4 A5 5 A4 6 A3 7 A2 8 A1 9 A0 10	AGEMENT 28 ¥cc 27 ¥E 26 CS2 25 A8 24 A9 23 A11 23 OE 21 A10 20 CS1 19 1/08



VE CS X H X X

H L H L

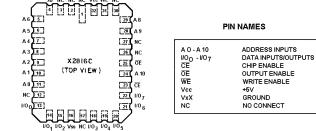
LL

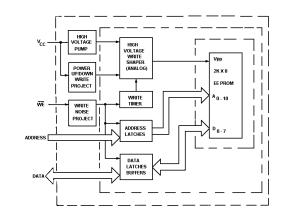
X=HORL

L

L

U6, Optoisolator 19A703952P102





<u>(15)</u> Y0

(13) Y2

(12) Y3

(11) Y4

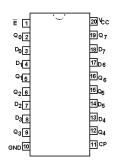
(14)

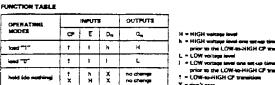
U5, 8K x 8-Bit Static CMOS RAM 19A705603P5 TRUTH TABLE

CS	OE	MODE	NO PIN
X	×	NOT SELECTED	HIGH Z
L	×	(POVER DOVN)	HIGH Z
н	H.	OUTPUT DISABLED	HIGH Z
н	L	READ	DOUT
н	н	VBITE	DIN
н	L	WINIE	DIN

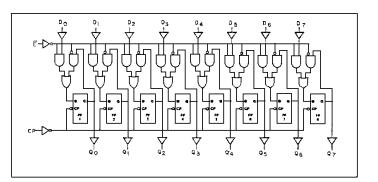
BLOCK DIAGRAM

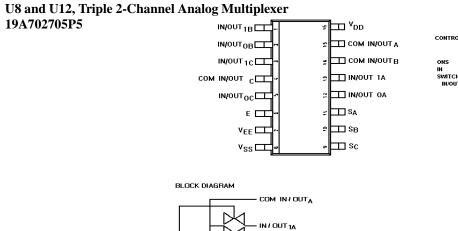
U7, CMOS Octal Data Flip-Flop 19A704380P319

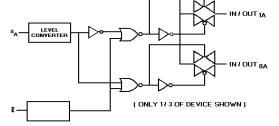


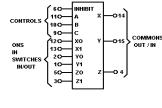


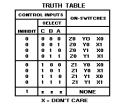
hold (do mostring) t h X no change X H X no change

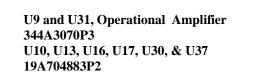




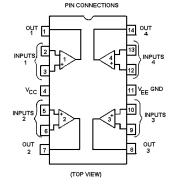




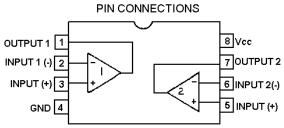




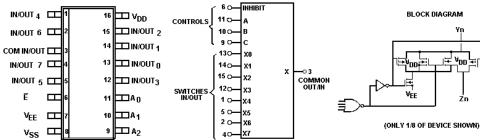




U11, Daul Op Amp 19A116297P7



U14, U32, & U33, 8-Channel Analog Multiplexer 19A702705P3



SYSTEM MODULE

X = DON'T CARE

0

0

0 0

0 0 0

CONTROL INPUTS

C B A 0 0 0

001

1 XXX NONE

NHIBIT SELECT ON-SWITCHES

XO

X1

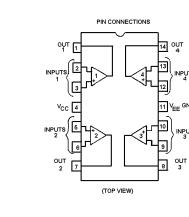
X2 X3

X4

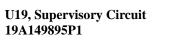
X5

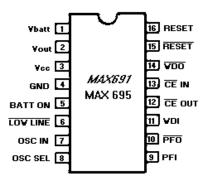
X6 X7





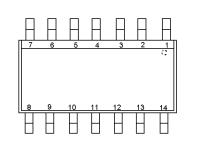






TOP VIEW

U18 and U28, CMOS Dual Data Flip-Flop 19A704380P302



Vcc

+4.4V (MAX xxx)

OSC IN 🛖

OSC SEL

WATCHDOG

POWER FAIL

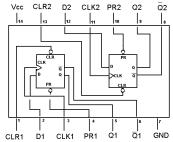
INPUTS

CLK

NOTE: Q0 = the level of Q before the indicated inout con-were established. * This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.

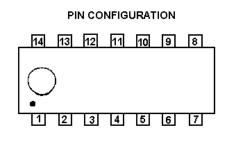
PR CLR

CHIP ENABLE

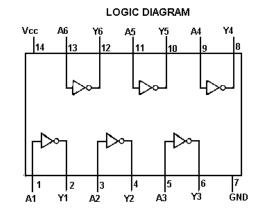




U21, IC 19A703995P3



SYSTEM MODULE



OUTPUTS

Q

ā

∟н ╫∟н Ю

BATT ON

RESET GENERATION

TMEBASE FOR RESE

AND WATCHDOG

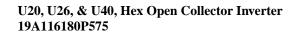
ATCHDOG TRANSISTOR DETECTOR

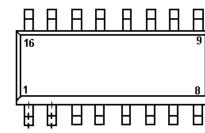
CHIP ENABLI

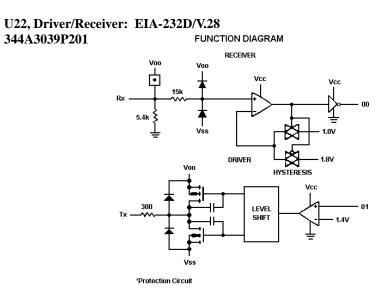
6 LOW LINE

16 RESET

RESET







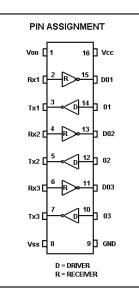
U24, Differential Bus Transceiver 19A705980P101 FUNCTION TABLE (DRIVER)

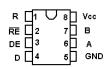
INPUT	INPUT ENABLE		ITPUTS
D	DE	A	В
Н	н	н	L
L	н	L	н
x	L	z	z
	ICTION TABLE (I		OUTPUT
DIFFERENTIAL		ENABLE	OUTPUT
			OUTPUT R
DIFFERENTIAL A - B V _{ID} > 0	INPUTS	ENABLE	
DIFFERENTIAL A - B V _{ID} > 0 -0.2V < V _{ID}	INPUTS 2V < 0.2V	ENABLE RE	R
DIFFERENTIAL A - B	INPUTS 2V < 0.2V	ENABLE RE	R

H = high level, L = low level, ? = indeterminate X = irrelevant, z = high impedance (off)

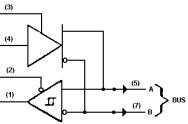
DE RF



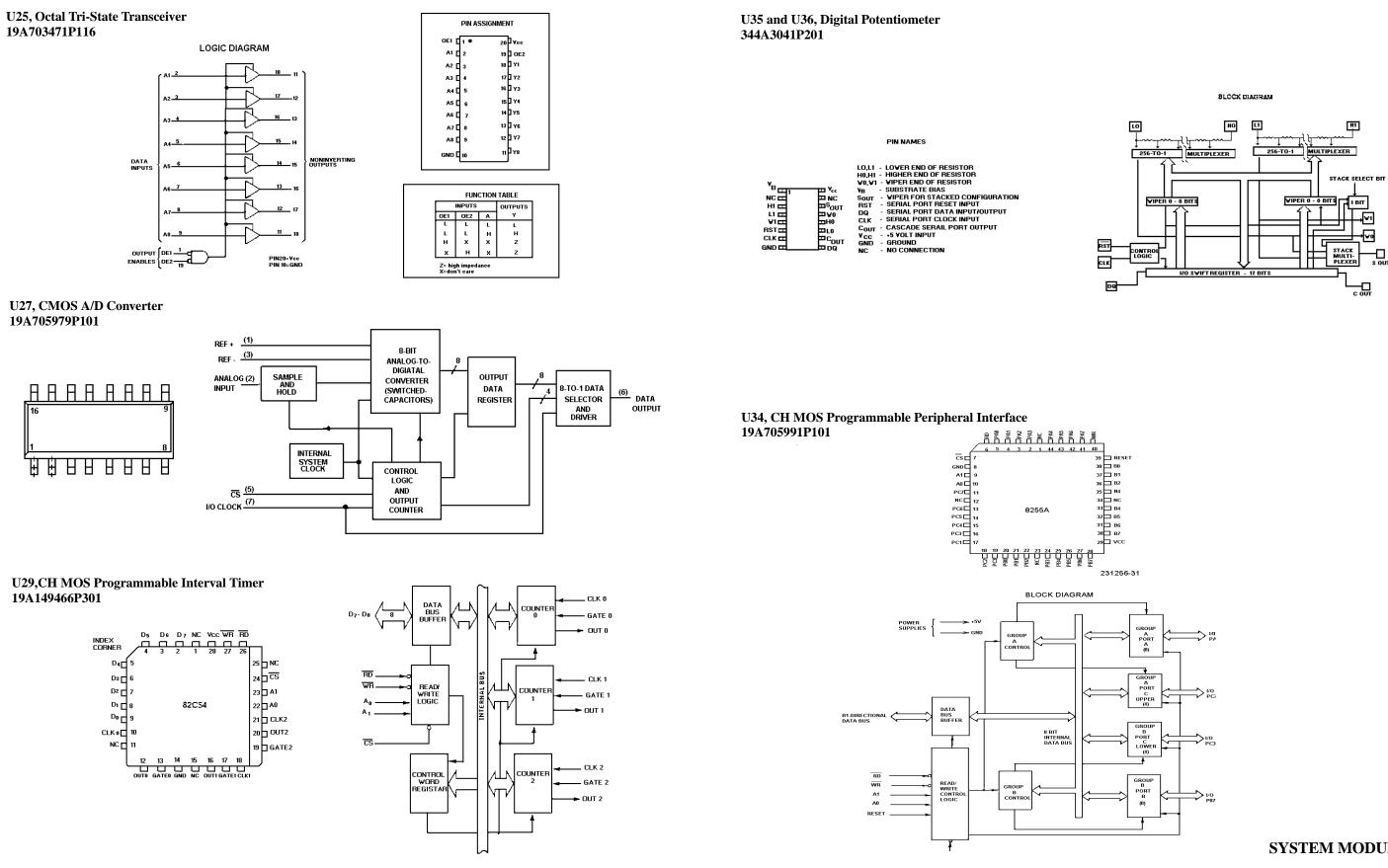




logic diagram (positive logic)



IC DATA



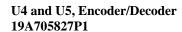
LBI-38764

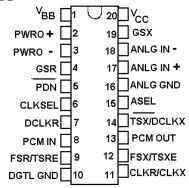
SYSTEM MODULE

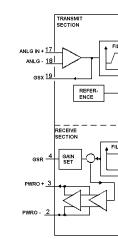
U41, Hex Inverting Buffer/Converter 19A700176P101

V<u>ss</u> 0, Ι, 03 I_{q} 1 2 3 4 5 6 7 8

• =		
U2 and U3, 8K x 8-Bit Stat 19A705603P5 PIN AF NC [A12 2 A7 3 A6 4 A5 5 A4 6 A3 7 A2 8 A1 9 A0 10 H01 11 H02 12 H03 13 V55 14	ic CMOS RAM RANGEMENT 24 Vcc 25 Vc 26 A8 24 A9 23 A11 22 CS2 29 A8 24 A9 23 A11 22 CS1 20	TRUTH TA $ \frac{VE CS CS OE MODE}{X H X MOT SELE} X L X (POVER D H L H H OUTPUT DE H L H H VRITE L L H H VRITE X=HORL $ BLOCK DIAGRAM T O SUFFER 64 = 8 64 = 8 $128 \times 64 \times 8$ 18 100 BUFFER 100 BUFFER 100 BUFFER 100 BUFFER 100 BUFFER





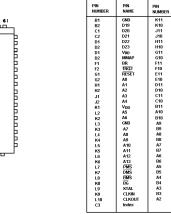


DSP BOARD

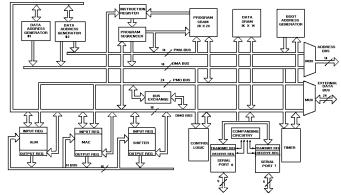


IC DATA

pin Name PIN PIN NUMBER NAME

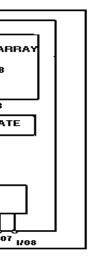


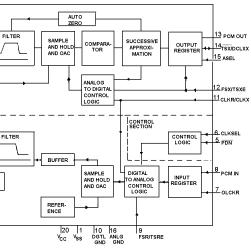
BLOCK DIAGRAM



UTH TABLE

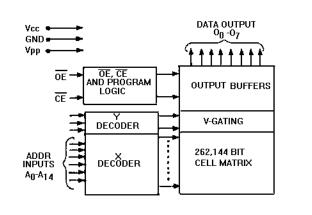
DDE	I/O PIN
ELECTED	HIGH Z
ER DOVN)	HIGH Z
T DISABLED	HIGH Z
AD	DOUT
BITE	DIN
	DIN





IC DATA

U6, EPROM Kit 344A3309G5



	070050		
_	27C256		
Урр 🗖 1	\bigcirc	28	D ∧cc
A12 2		27	
A7 🗖 3		26	
A6 🗖 4		25	
A5 🗖 5		24	1 A9
A4 🗖 6		23	
A3 7		22	DOE
A2 🗖 8		21	A 10
A1 🗖 9		20	DCE
A0 10	1	19	1 07
00011		18	06
01012		17	05
02 13		16	□ 04
		15	Þ 03

PIN	NAME
An 1A14	ADDRESSES
CE	CHIP ENABLE
OE	OUTPUT ENABLE
0 ₀ - 0 ₇	OUTPUTS

A0 1	16 _{Vcc}
A1_2	<u>15</u> 70
A2_3	14 ₇₁
Ē1_4	13 <u>7</u> 2
E2 5	12 y3
E3_6	<u>11</u> . 74
<u>77</u> 7	<u>10</u> 75
GND-8	9 76
	,

344A3064P201

					TR	JTH	ТАВ	LE			
16 Vcc			INPUT	rs						ол	PUTS
15 VO	EN/	ABLE		(AD	DRES	S	I				
	E3	E2	Ē1	(A2	A1	A0	ÝÖ	Y1	Y2	Y3	¥4
14 yı	X	x	Н	x	x	x	н	Н	Н	Н	н
13 🕁	L	x	х	x	х	х	H	н	н	н	н
13 ¥2	X	Н	х	x	х	х	н	н	н	н	н
12 ,	H H	Ľ	L	L	Ľ	L	1.	н	н	н	Н
μ έ γ <u>3</u>	н	L	L	L	L	н	н	L.	н	н	н
	н	L	L	L	н	L	н	н	L	н	н
<u>11. 74</u>	н	L	L	L	н	н	н	н	н	L	н
	н	L	L	н	L	L	н	н	н	н	L
10 ys	н	L	L	н	L	н	н	н	н	н	н
	Ιн	L	L	н	н	L	н	н	н	н	н
9 76	Ĥ	L	Ē	H	Н	H	н	H	Н	Н	н
_	H = HIG	SH LEV	ΈL. L	= LOW	LEVE	L. X =	DON'	r cari	E		

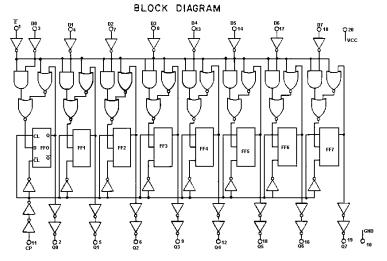
U7, CMOS Hi-Speed Octal D Type Flip-Flop With Data Enable 344A3064P203

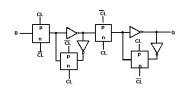
È-L	-	20 VCC
Q0 2		<u>19 Q7</u>
D0 <u>3</u>		18 D7
D1 4		17 D6
Q1 5		16 Q6
Q2_6		15 _{Q5}
D2 7		14 D5
D3 _8		13 D4
Q3 9		12 Q4
GND 10		11 _{CP}
		1

TRUTH TABLE

	INPUTS			OUTPUTS
OPERATING MODE	СР	E	Dn	On
LOAD "1"	,	-	h	н
LOAD "0"	~	1	X	L
HOLD (do nothing)	~	h	x	no change no change

H= HIGH Voltage level steady state. h= HIGH Voltage level one setup time prior to the LOWto-HIGH clock transition L= LOW voltage level steady state. I = LOW voltage level one setup time prior to the LOWto - HIGH clock transition X = Don't care ✓ = LOW to -HIGH clock





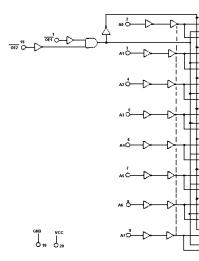
U9, CMOS Hi-Speed Octal Buffer/Line Driver, 3 State 344A3064P204

U8, CMOS Hi-Speed 3 To 8 Line Decoder/Demultiplexer

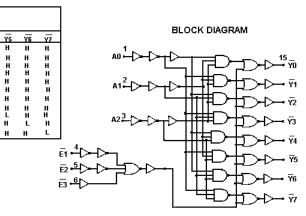
0EI _1	$ \frown $	20 VCC
A0 _2		19 0E2
A1 _3		18 Y0
A2 _4		<u>17.</u> Y1
A3 _5		<u>16</u> Y2
A4		<u>15</u> Y3
A5		14 Y4
A6 <u>8</u>		13 Y5
A7		12 Y6
GND 10		<u>11</u> y7

	٦
	INPUTS
OE1	OE2
L	L
н	x
х	н
L	L
	H = H L = L(X = Im Z = Hi

BLOCK DIAGRAM



LBI-38764

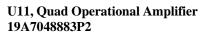


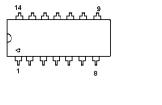
TRUTH TABLE

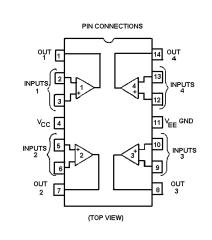
	OUTPUTS
An	
н	н
х	Z
х	z
L	L

HIGH Voltage Level LOW Voltage Level Immaterial High Impedance

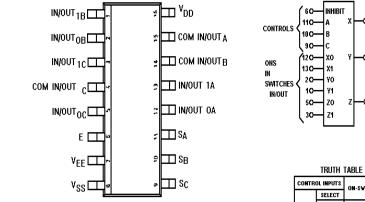
DSP BOARD

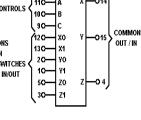




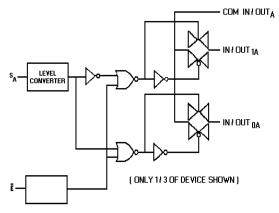


U10, Triple 2-Channel Analog Multiplexer 19A702705P5



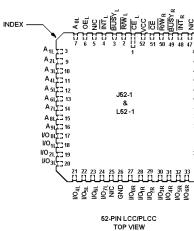




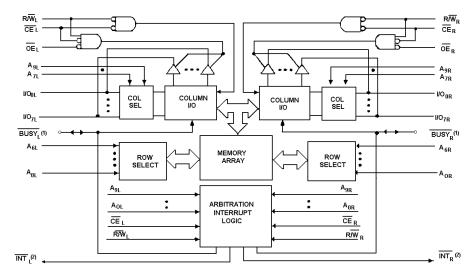


IRUTH TABLE						
CONTROL INPUTS		ON-SWITCHES				
	SELECT					
INHIBIT	С	в	А			
0	0	0	0	ZO	YO	X0
0	0	0	1	ZO	YO	X1
0	0	1	0	ZO	Y1	X0
0	0	1	1	ZO	Y1	X1
0	1	0	0	Z1	YO	X0
0	1	0	1	Z1	YO	X1
0	1	1	0	Z1	Y1	X0
0	1	1	1	Z1	Y1	X1
1	z	z	z		NON	E
X = DON'T CARE						

U12, SRAM, 1K x 8, Dual Port 344A3040P201



BLOCK DIAGRAM



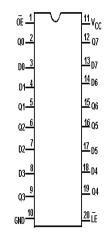
NOTES: 1. IDT7130 (MASTER): BUSY IS OPEN DRAIN OUTPUT AND REQUIRES PULLUP RESISTOR. IDT7140(SLAVE): BUSY IS INPUT. 2. OPEN DRAIN OUTPUT REQUIRES PULLUP RESISTOR.

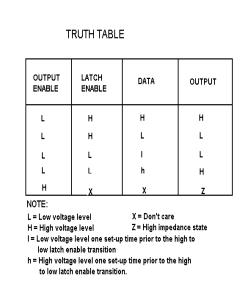
DSP BOARD

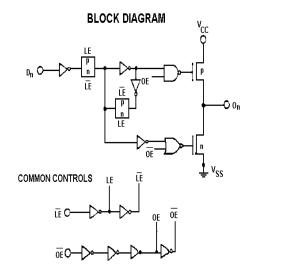


IC DATA

U13, CMOS Hi-Speed Octal Transparent Latch 344A3064P202







¹⁴☆☆☆☆☆☆☆☆) ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓

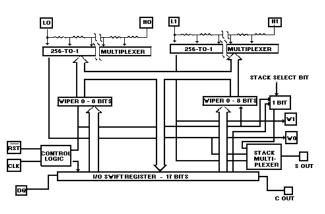
U17, Triple 2-Channel Analog Multiplexer 19A702705P5

	-
IN/OUT _{OB}	~
	~
COM IN/OUT C	4
IN/OUT _{OC}	r.
E CT	ы
V _{EE}	*-
v _{ss} 🗖	æ

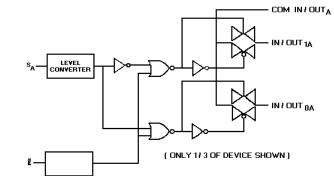
U15, Digital Potentiometer 344A3041P201

PIN NAMES LO.L1 - LOVER END OF RESISTOR HO.H1 - HIGHER END OF RESISTOR V0.V1 - VIPER END OF RESISTOR V0.V1 - VIPER END OF RESISTOR V0.V1 - VIPER FOR STACKED CONFIGURATION HI D'NC SOUT - VIPER FOR STACKED CONFIGURATION HI D'NC SERIAL PORT DATA INPUT/OUTPUT LI D'V0 DQ - SERIAL PORT CLOCK INPUT VII DH0 CLK - SERIAL PORT CLOCK INPUT VII DH0 CLK - SERIAL PORT CLOCK INPUT CLK D'COUT GND - GROUND GND D DQ NC - NO CONNECTION





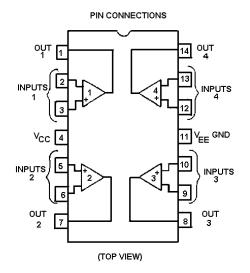
BLOCK DIAGRAM

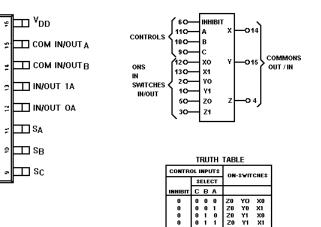


U16, Operational Amplifier

344A3070P3

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LBI-38764
```





DSP BOARD

 0
 0
 Z1
 Y0
 X0

 0
 1
 Z1
 Y0
 X1

 1
 0
 Z1
 Y1
 X0

 1
 1
 Z1
 Y1
 X1

 1
 1
 Z1
 Y1
 X1

1 z z z NONE

X = DON'T CARE